## 2020

## Panasonic INDUSTRY

### **Fixed Resistors**

Products Catalog



# Guidelines and precautions regarding the technical information and use of our products described in this online catalog.

- If you want to use our products described in this online catalog for applications requiring special qualities or reliability, or for applications where the failure or malfunction of the products may directly jeopardize human life or potentially cause personal injury (e.g. aircraft and aerospace equipment, traffic and transportation equipment, combustion equipment, medical equipment, accident prevention, anti-crime equipment, and/or safety equipment), it is necessary to verify whether the specifications of our products fit to such applications. Please ensure that you will ask and check with our inquiry desk as to whether the specifications of our products fit to such applications use before you use our products.
- The quality and performance of our products as described in this online catalog only apply to our products when used in isolation. Therefore, please ensure you evaluate and verify our products under the specific circumstances in which our products are assembled in your own products and in which our products will actually be used.
- If you use our products in equipment that requires a high degree of reliability, regardless of the application, it is recommended that you set up protection circuits and redundancy circuits in order to ensure safety of your equipment.
- The products and product specifications described in this online catalog are subject to change for improvement without prior notice. Therefore, please be sure to request and confirm the latest product specifications which explain the specifications of our products in detail, before you finalize the design of your applications, purchase, or use our products.
- The technical information in this online catalog provides examples of our products' typical operations and application circuits. We do not guarantee the non-infringement of third party's intellectual property rights and we do not grant any license, right, or interest in our intellectual property.
- If any of our products, product specifications and/or technical information in this online catalog is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially with regard to security and export control, shall be observed.

## < Regarding the Certificate of Compliance with the EU RoHS Directive/REACH Regulations>

- The switchover date for compliance with the RoHS Directive/REACH Regulations varies depending on the part number or series of our products.
- When you use the inventory of our products for which it is unclear whether those products are compliant with the RoHS Directive/REACH Regulation, please select "Sales Inquiry" in the website inquiry form and contact us.

We do not take any responsibility for the use of our products outside the scope of the specifications, descriptions, guidelines and precautions described in this online catalog.



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### Safety Precautions (Common precautions for Fixed Resistors)

- When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products under the actual conditions for use.
- Install the following systems for a failsafe design to ensure safety if these products are to be used in equipment where a defect in these products may cause the loss of human life or other significant damage, such as damage to vehicles (automobile, train, vessel), traffic lights, medical equipment, aerospace equipment, electric heating appliances, combustion/gas equipment, rotating equipment, and disaster/crime prevention
- \* Systems equipped with a protection circuit and a protection device.
- \* Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single
- \* Systems equipped with an arresting the spread of fire or preventing glitch.

### (1) Precautions for use

- These products are designed and manufactured for general and standard use in general elec tron ic equipment. (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment) For applications in which special quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or cause threat of personal injury (such as for aircraft and aerospace equipment, traffic and transport equipment, combustion equipment, medical equipment, accident prevention and anti-theft devices, and safety equipment), please be sure to consult with our sales representative in advance and to exchange product specifications which conform to such applications.
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
  - 1. In liquid, such as water, oil, chemicals, or organic solvent.
  - 2. In direct sunlight, outdoors, or in dust.
  - 3. In salty air or air with a high concentration of corrosive gas, such as  $Cl_2$ ,  $H_2S$ ,  $NH_3$ ,  $SO_2$ , or  $NO_X$ .
  - 4. Electric Static Discharge (ESD) Environment.
    - These components are sensitive to static electricity and can be damaged under static shock (ESD). Please take measures to avoid any of these environments.
    - Smaller components are more sensitive to ESD environment.
  - 5. Electromagnetic and Radioactive Environment.
    - Avoid any environment where strong electromagnetic waves and radiation exist.
  - 6. In an environment where these products cause dew condensation.
  - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials.
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- · Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to leave water residues. Otherwise, the insulation performance may be deteriorated.
- Do not apply flux to these products after soldering. The activity of flux may be a cause of failures in these products.
- Refer to the recommended soldering conditions and set the soldering condition. High peak temperature or long heating time may impair the performance or the reliability of these products.
- · Recommended soldering condition is for the guideline for ensuring the basic characteristics of the products, not for the stable soldering conditions. Conditions for proper soldering should be set up according to individual conditions.



- Do not reuse any products after removal from mounting boards.
- Do not drop these products. If these products are dropped, do not use them. Such products may have received mechanical or electrical damage.
- If any doubt or concern to the safety on these products arise, make sure to inform us immediately and conduct technical examinations at your side.

### (2) Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- 1. In salty air or in air with a high concentration of corrosive gas, such as Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, or NO<sub>X</sub>.
- 2. In direct sunlight.

### (3) AEC-Q200 Compliant

The products are tested based on all or part of the test conditions and methods defined in AEC-Q200. Please consult with Panasonic for the details of the product specification and specific evaluation test results, etc., and please review and approve Panasonic's product specification before ordering.

<Package markings>

Package markings include the product number, quantity, and country of origin.

In principle, the country of origin should be indicated in English.



### Safety Precautions (Common precautions for Surface Mount Resistors)

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- Take measures against mechanical stress during and after mounting of Surface Mount Resistors (hereafter called the resistors) so as not to damage their electrodes and protective coatings. Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- Keep the rated power and ambient temperature within the specified derating curve. Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temper a tures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and op timize them so as not to damage the boards and peripheral components.
  - Make sure to contact us before using the resistors under special conditions.
- If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use. Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- Transient voltage If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions.
- If the resistors are to be used in high frequency circuits, carefully check the operation before use. 5. Such circuits change the electrical characteristics of the resistors.
- Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the 6. performance and reliability of the resistors.
- 7. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- Mounting of the resistors with excessive or insufficient wetting amount of solder may affect the connection reliability or the performance of the resistors. Carefully check the effects and apply a proper amount of solder for use.
- When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the 9. resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 10. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 11. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 12. Do not immerse the resistors in solvent for a long time. Before using solvent, carefully check the effects of immersion.
- 13. Do not apply excessive tension to the terminals.



### **Thick Film Chip Resistors**

### **Thick Film Chip Resistors**

Series: ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T

102

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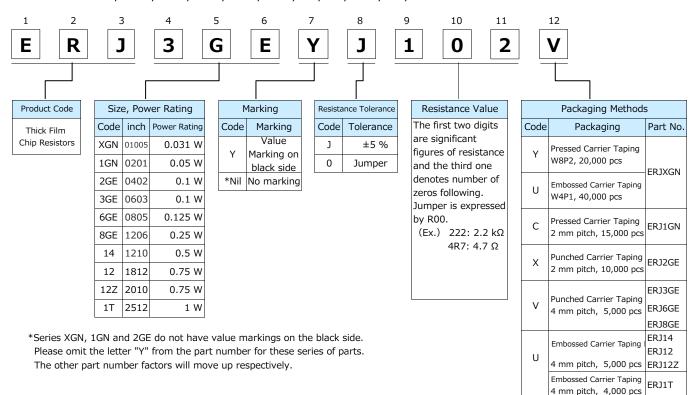
102

### **Features**

- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**

• Series ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T, ±5 %



### Ratings

### **[For Resistor]**

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resista Rang (Ω)	ge	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10 Ω : -100 to +600 10 Ω to 100 Ω : ±300 100 Ω≤R : ±200	-55 to +125	-
ERJ1G (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	R<10 Ω :	-55 to +155	Grade 0
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	-100 to +600	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω :	-55 to +155	Grade 0
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)	±200	-55 to +155	Grade 0
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	1 MΩ <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	-400 to +150	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)		-55 to +155	Grade 0
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)		-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

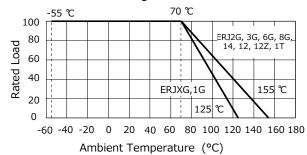
#### [For Jumper]

ti oi sai	ti di bamperi										
Part No.	Resistance( $\Omega$ )	Rated Current(A)	Maximum Overload Current (A) <sup>(1)</sup>								
ERJXG		0.5	1								
ERJ1G		0.5	1								
ERJ2G		1	2								
ERJ3G		1	2								
ERJ6G	50 mΩ or less										
ERJ8G	30 1112 Of 1655										
ERJ14		2	4								
ERJ12		2	4								
ERJ12Z											
ERJ1T											

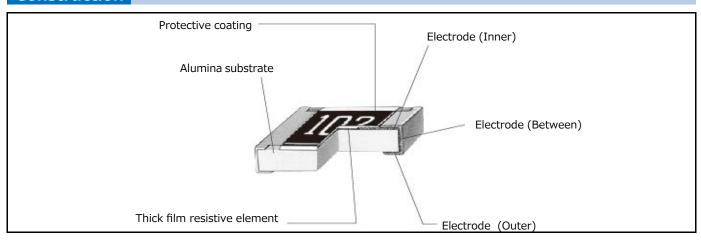
(1) Overload test current

### **Power Derating Curve**

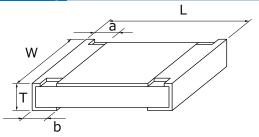
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



### Construction



### Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
rait No.	L	W	a	b	Т	(g/1000 pcs)			
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8			
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

### Performance

Took Itom	Performance Re	equirements ⊿R	Test Conditions		
Test Item	Resistor type	Jumper type			
Resistance	Within Specified Tolerance	50 mΩ or less	20 °C		
T. C. R.	Within Specified T. C. R.	50 mΩ or less	+25 °C/+155 °C (ERJXG,1G : +25 °C/+125 °C)		
Overload	±2 %	50 mΩ or less	Rated Voltage× 2.5, 5 s  Jumper type: Max. Overload Current, 5 s		
Resistance to Soldering Heat	±1 %	50 mΩ or less	270 °C, 10 s		
Rapid Change of Temperature	±1 %	50 mΩ or less	-55 °C (30 min.) / +155 °C (ERJXG,1G: +125 °C) (30 min.), 100 cycles		
High Temperature Exposure	±1 %	50 mΩ or less	+155 °C (ERJXG,1G: +125 °C), 1000 h		
Damp Heat, Steady State	±1 %	50 mΩ or less	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	50 mΩ or less	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type : Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	50 mΩ or less	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		



### **Precision Thick Film Chip Resistors**

### **Precision Thick Film Chip Resistors**

Series: ERJ XG, 1G

ERJ 1R, 2R, 3R, 6R

ERJ 3E, 6E, 8E, 14, 12, 1T







1001

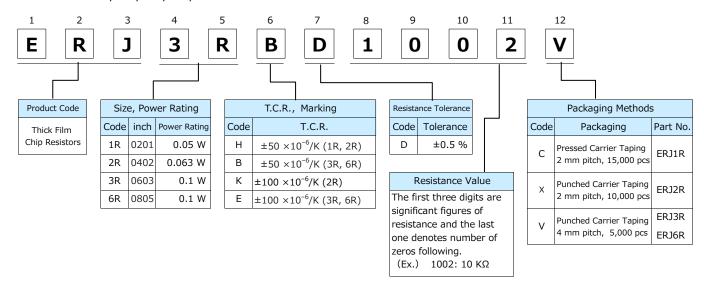
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### **Features**

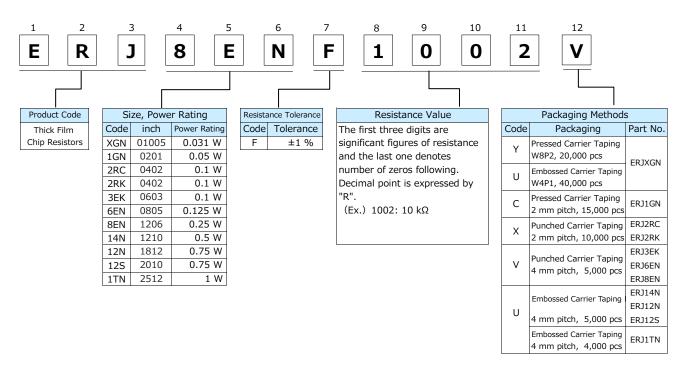
- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Low Resistance Tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T : ±1 % ERJ1R, 2R, 3R, 6R : ±0.5 %
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG, ERJ1R)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**

• Series ERJ1R, 2R, 3R, 6R, ±0.5 %



• Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %



### **Ratings**

#### <±0.5 %>

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resist Ran (Ω	ge	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3RB (0603)	0.1	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ3RE (0603)	0.1	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

### Ratings

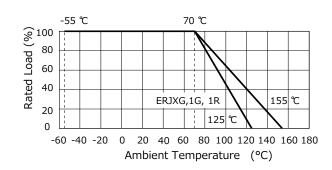
### <±1 %>

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resista Rang (Ω)	е	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M <sup>(4)</sup>	(E24,E96)	R<100 Ω : ±300 100 Ω ≤R : ±200	-55 to +125	-
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M <sup>(4)</sup>	(E24,E96)	±200	-55 to +125	Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600	-55 to +155	Grade 0
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

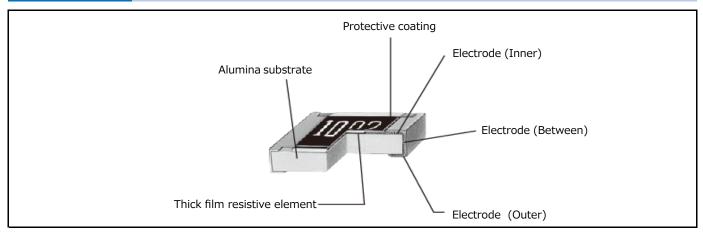
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) Please contact us when you need a type with a resistance of less than 10  $\Omega.\,$

#### **Power Derating Curve**

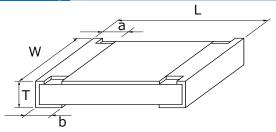
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



### Construction



### Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
Part No.	L	W	a	b	Т	(g/1000 pcs)			
ERJXGN	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJ1GN ERJ1R□	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJ2R□	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8			
ERJ3R□ ERJ3EK	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJ6R□ ERJ6EN	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

### Performance

• Series ERJ1R, 2R, 3R, 6R, ±0.5 %(D)

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (ERJ1R : +125 °C)(30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C (ERJ1R: +125 °C), 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,
Load Life in Humidity	ERJ1R: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±2 % ERJ1R : ±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

### ● Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %(F)

Test Item	Performance	Test Conditions			
rest item	Requirements ⊿R	rest conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 °C			
T. C. R.	Within Specified	+25 °C/+155 °C (ERJXG,ERJ1G : +25℃/+125 °C)			
1. C. K.	T. C. R.	+25 °C/+155 °C (ERJAG,ERJ1G : +25 C/+125 °C)			
Overload	±2 %	Rated Voltage× 2.5, 5 s			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
Rapid Change of Temperature	±1 %	-55 °C (30 min.)/+155 °C (ERJXG,ERJ1G: +125 °C)(30 min.),			
Rapid Change of Temperature	<b>11</b> 70	100 cycles			
High Temperature Exposure	±1 %	+155 °C (ERJXG,ERJ1G: +125 °C), 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life III Fluirilaity	ERJXG,1G: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±2 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Eliuliance at 70 °C	ERJXG,1G: ±3 %	70 °C, Rated Voltage, 1.5 ii ON / 0.5 ii OFF Cycle, 1000 ii			

### Thin Film Chip Resistors, High Stability and Reliability Type

### NEW

## Thin Film Chip Resistors, High Stability and Reliability Type

### **ERA V (High resistance value ERA K)**

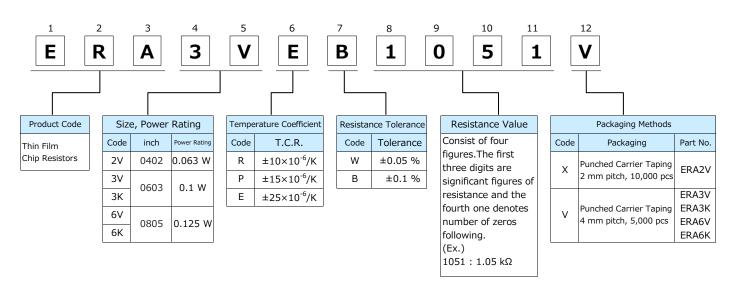
Series: ERA 2V, 3V, 6V (Series: ERA 3K, 6K)



### **Features**

- High reliability...... Stable at high temperature and humidity
  - (85 °C 85 %RH rated load, Category temperature range: -55 °C to +155 °C)
- High accuracy ..... Low resistance tolerance and Temperature Coefficient of Resistance
- High performance… Low current noise, excellent linearity
- Anti-ESD Original structure for high ESD performance
  - (AEC-Q200-002 HBM Level 1c and above)
- Anti-sulfurated ······· Original structure for sulfurated performance
- Reference Standard ······ IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**

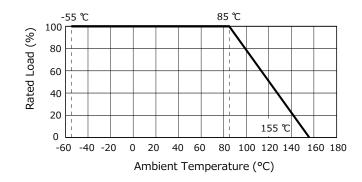


Rat	ings									
Part No. (inch size)	Power Rating at 85 °C <sup>(1)</sup>	Limiting Element Voltage <sup>(2)</sup>	Maximum Overload Voltage <sup>(3)</sup>	Part No.   Resistance   T.C.R.   Resistance Range <sup>(4)</sup>		T.C.R. Resistance Range <sup>(4)</sup> Temperat		Category Temperature Range	AEC-Q200 Grade	
	(W)	(V)	(V)		(%)	(×10 <sup>-6</sup> /K)	2)	5)	(℃)	
				ERA2VEB	±0.1	±25	47 to 10 k	(E24, E96)		
ERA2V	0.063	50	100	ERA2VPB	±0.1	±15				
(0402)	0.005	30	100	ERA2VRB	±0.1	1 K to 10 k	1 K to 10 k	(E24, E96)		
			ERA2VRW	±0.05	110					
				ERA3VEB	±0.1	±25	47 to 100 k	(E24, E96)		
ERA3V	ERA3V 0.1 75	150	ERA3VPB	±0.1	±15					
(0603)	0.1	73	130	ERA3VRB	±0.1	±10	1 K to 100 k	(E24, E96)	55 to +155	Cua da O
				ERA3VRW	±0.05	110				
ERA3K (0603)	0.1	75	150	ERA3KEB	±0.1	±25	102 K to 240 l	< (E24, E96)	-55 (0 +155	Grade 0
				ERA6VEB	±0.1	±25	47 to 100 k	(E24, E96)		
ERA6V	0.125	100	200	ERA6VPB	±0.1	±15				
(0805)	0.125	100	200	ERA6VRB	±0.1	±10	1 K to 100 k	(E24, E96)		
			ERA6VRW	±0.05	±10					
ERA6K (0805)	0.125	100	200	ERA6KEB	±0.1	±25	102 K to 750 l	< (E24, E96)		

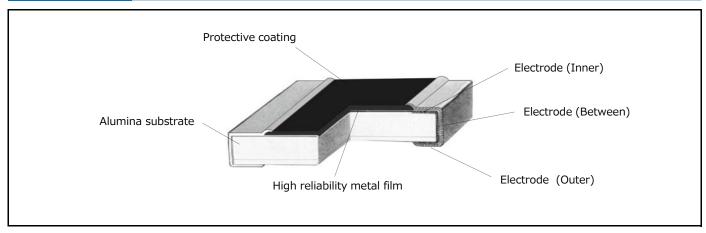
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5)  $\times$  RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

### **Power Derating Curve**

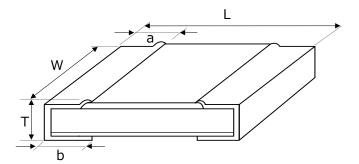
For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



### Construction



### **Dimensions in mm (not to scale)**



Part No. Dimensions (mm)								
Part No.	L	W	a	b	Т	(g/1000 pcs)		
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6		
ERA3V, 3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2		
ERA6V, 6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5		

### Performance

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±0.1 %	Rated Voltage× 2.5, 5 s		
Resistance to ±0.1 %		270 °C, 10 s		
Rapid Change of ±0.1 %		-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles		
High Temperature ±0.1 %		+155 °C, 1000 h		
Damp Heat, Steady State	±0.1 %	85 °C, 85 %RH, 1000 h		
Load Life in Humidity	±0.1 %	85 °C, 85 %RH, 10 % of Rated Power <sup>(1)</sup> , 1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 85 °C	±0.1 %	85 °C , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Electro Static Discharge (HBM)	±0.1 % <sup>(2)</sup>	AEC-Q200-002 : 150 pF, 2000 $\Omega$ , positive 5 times, negative 5 times ERA2V : 1.0 kV (level 1c) ERA3V(3K) : 1.5 kV (level 1c) ERA6V(6K) : 2.0 kV (level 2)		

 $<sup>(1) \ \</sup>text{Applied Voltage is "} \\ \sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}} \ \text{", or "Limiting Element Voltage} \\ \times 0.316 \\ \text{", whichever less.}$ 

<sup>(2)</sup> Depends on resistance value.



## Metal Film (Thin Film) Chip Resistors, High Reliability Type

102 102

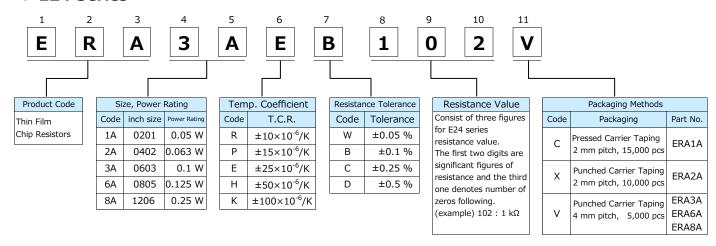
Series: ERA 1A, 2A, 3A, 6A, 8A

### **Features**

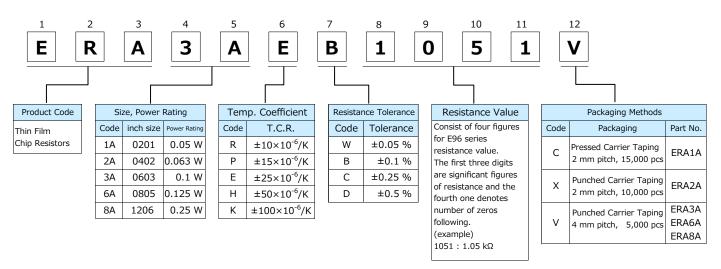
- High reliability ..... Stable at high temperature and humidity
  - (85 °C 85 %RH rated load, Category temperature range: -55 °C to +155 °C)
- High accuracy·······Low resistance tolerance and Temperature Coefficient of Resistance
- High performance...Low current noise, excellent linearity
- Reference Standard ······ IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- AEC-Q200 compliant (except ERA1A)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**

### E24 Series



### E96 Series and other Resistance values



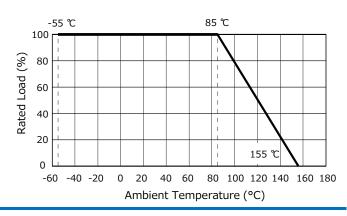
Note: Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Rat	ings									
Part No. (inch size)	Power Rating at 85 °C <sup>(1)</sup>	Limiting Element Voltage <sup>(2)</sup>	Maximum Overload Voltage <sup>(3)</sup>	Part No. (detail)	Resistance Tolerance	T.C.R.	Resista Range <sup>(</sup>		Category Temperature Range	AEC-Q200 Grade
	(W)	(V)	(V)		(%)	(×10 <sup>-6</sup> /K)	(Ω)		(℃)	
				ERA1AEB	±0.1	±25	100 to 10 k	(E24,E96)		
ERA1A				ERA1AEC	±0.25	123	100 to 10 k	(L24,L30)		
(0201)	0.05	25	50	ERA1ARC	±0.25		100 to 10 k	(E24,E96)		-
(0201)				ERA1ARB	±0.1	±10	100 to 10 k	(LZ4,L30)		
			ERA1ARW	±0.05		1 k to 10 k	(E24,E96)			
				ERA2AKD	±0.5	±100	10 to 46.4	(E24,E96)		
			ERA2AED	±0.5						
				ERA2AEC	±0.25	±25	47 to 100 k	(E24,E96)		
ERA2A (0402) 0.063 50	50	100	ERA2AEB	±0.1					Grade 1	
	33	100	ERA2APC	±0.25	±15	200 to 47 k	(E24,E96)		0.0001	
				ERA2APB	±0.1	-13	200 to 17 K	(== :/=55)		
			ERA2ARC	±0.25	±10	200 to 47 k	(E24,E96)	i)		
			ERA2ARB	±0.1						
				ERA3AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA3AED	±0.5					
			ERA3AEC	±0.25	±25	47 to 330 k	(E24,E96)			
FRA3A	ERA3A 0.1		5 150	ERA3AEB	±0.1					
(0603)		75		ERA3APC	±0.25	±15	470 to 100 k	(E24,E96)		Grade 0
,				ERA3APB	±0.1					
				ERA3ARC	±0.25	±10				
				ERA3ARB	±0.1		1 k to 100 k	(E24,E96)		
				ERA3ARW	±0.05					
				ERA6AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA6AED	±0.5			(== , == =)		
				ERA6AEC	±0.25	±25	47 to 1 M	(E24,E96)		
ERA6A				ERA6AEB	±0.1					
(0805)	0.125	100	200	ERA6APC	±0.25	±15	470 to 100 k	(E24,E96)		Grade 0
				ERA6APB	±0.1					
				ERA6ARC	±0.25	1.10	4 1. 5. 400 1.	(524 506)		
				ERA6ARB	±0.1	±10	1 k to 100 k	(E24,E96)		
				ERA6ARW	±0.05	1.50	10 - 16 1	(F24 F0C)		
				ERA8AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERASAED	±0.5	±25	47 to 1 M	(E24 E06)		
				ERASAEC	±0.25	<b>±2</b> 5	47 to 1 M	(E24,E96)		
ERA8A	0.25	150	300	ERASAEB	±0.1					Crado C
(1206)	0.25	0.25 150	0 300	ERASAPC	±0.25	±15	470 to 100 k	(E24,E96)		Grade 0
	` '			ERA8APB ERA8ARC	±0.1			, , 7		
			ERA8ARC ERA8ARB	±0.25 ±0.1	±10	1 k to 100 k	(E24 E06)			
						±10	1 K (O 100 K	(E24,E96)	6)	
				ERA8ARW	±0.05					

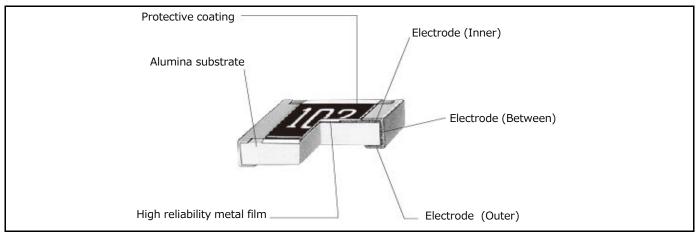
- (1) Use it on the condition that the case temperature is below the upper category  $\underline{\text{temperature}}$ .
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5)  $\times$  RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) E192 series resistance values are also available. Please contact us for details.
- (5) Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

### **Power Derating Curve**

For resistors operated in ambient temperatures above  $85\,^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

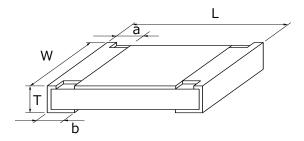


### Construction



<sup>\*0402</sup> size, 0603 size and E96 series do not have value markings.

### **Dimensions in mm (not to scale)**



Part No.	Dimensions (mm)								
rait No.	L	W	a	b	Т	(g/1000 pcs)			
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14			
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3A	1.60±0.20	0.8±0.20	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.60±0.10	4			
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8			



### **High Precision Thick Film Chip Resistors**

## **High Precision Thick Film Chip Resistors**

1004

Series: ERJ PB3, PB6

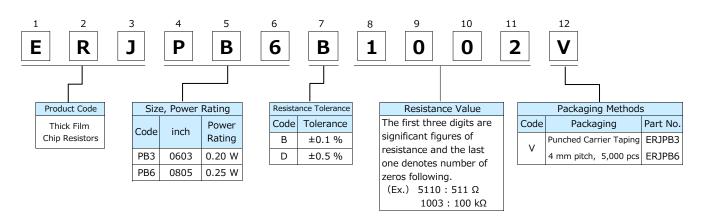
### **Features**

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance  $\pm 50 \times 10^{-6}$ /K in high resistance range up to 1 M $\Omega$
- High power ··· 0.20 W : 0603 inch /1608 mm size (ERJPB3)

0.25 W: 0805 inch /2012 mm size (ERJPB6)

- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**



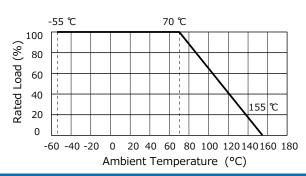
### **Ratings**

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJPB3	0.20	150	200	±0.1	200 to 100 k	±50	-55 to +155	Grade 0
(0603)	0.20	130	200	±0.5	(E24, E96)	_50	33 to 1133	Grade o
ERJPB6	0.25	150	200	±0.1	200 to 1 M	±50	-55 to +155	Grado 0
(0805)	0.25	130	200	±0.5	(E24, E96)	±30	-33 10 +133	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance)  $\times$  RCWV or Maximum Overload Voltage listed above, whichever less.

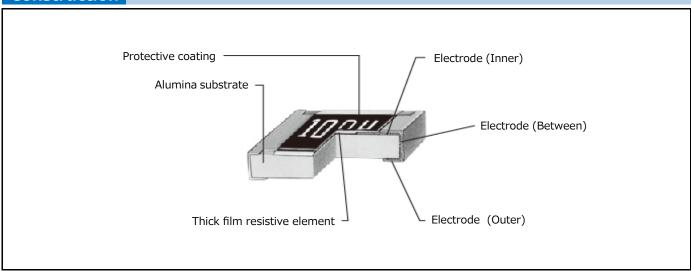
#### **Power Derating Curve**

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

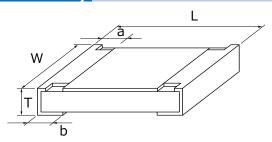


### **High Precision Thick Film Chip Resistors**

### Construction



### Dimensions in mm (not to scale)



Part No.	Dimensions (mm)						
rait No.	L	W	a	b	Т	(g/1000 pcs)	
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	

### Performance

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±0.5 %	Rated Voltage× 2.0, 5 s
Resistance to Soldering Heat	±0.5 %	270 °C, 10 s
Rapid Change of Temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±0.5 %	+155 °C, 1000 h
Damp Heat, Steady State	±0.5 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±0.5 %	60 °C, 90 % to 95 %RH, Rated Voltage,
Load Life III Hulflidity	10.5 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±0.5 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



### Thick Film Chip Resistors / Low Resistance Type

## Thick Film Chip Resistors / Low Resistance Type

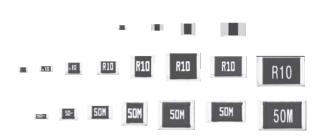
Series: ERJ 2LW, 3LW, 6LW,

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

ERJ 2B, 3B, 6D, 6B, 8B, 14B,

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR

ERJ L03, L06, L08, L14, L12, L1D, L1W

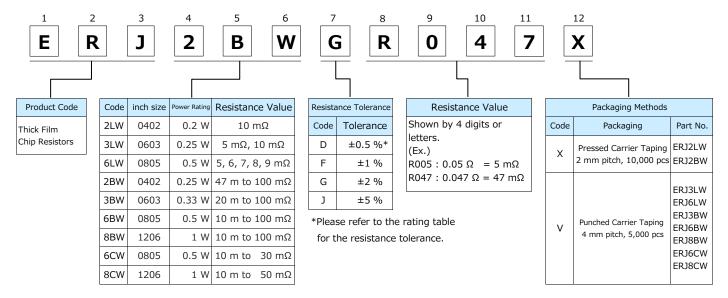


#### Features

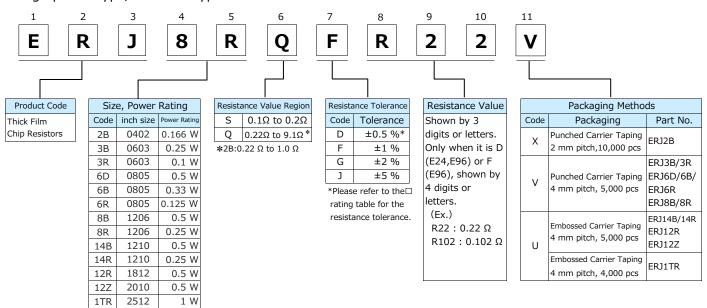
- Current Sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising… ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR····· ±75×10<sup>-6</sup>/K (ERJ6CW, ERJ8CW)
- Low Resistance Value ··· Thick film resistors available from 5 m $\Omega$  (ERJ3LW, 6LW)
- Reference Standard ..... IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**

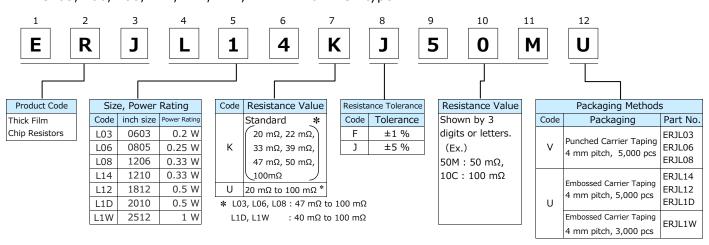
ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
 High power (double-sided resistive elements structure) type>



• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR < High power type/Standard type>



• ERJL03, L06, L08, L14, L12, L1D, L1W <Low TCR type>



### **Ratings**

< High power (double-sided resistive elements structure) type>

Part I (inch s		Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range <sup>(2)</sup> (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJ2LW	(0402)	0.2	±1, ±2, ±5	10 m	0 to +500	-55 to +125	Grade 1
ERJ3LW	(0603)	0.25	±1, ±2, ±5	5 m	0 to +700	-55 to +125	Grade 1
EKJSLW	(0003)	0.25	11, 12, 13	10 m	0 to +300	-55 to +125	Graue 1
ERJ6LW	(0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300	-55 to +125	Grade 1
ERJ2BW	(0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300	-55 to +155	Grade 0
ERJ3BW	(0603)	0.33	±1, ±2, ±5	20 m to 100 m (E24)	20 mΩ ≤ R < 39 mΩ:0 to +250 39 mΩ ≤ R ≤ 100 mΩ:0 to +150	-55 to +155	Grade 0
ERJ6BW	(0805)	0.5	±1, ±2, ±5	10 m to 100 m (E24)	10 mΩ ≤ R < 15 mΩ:0 to +300 15 mΩ ≤ R ≤ 100 mΩ:0 to +200	-55 to +155	Grade 0
ERJ8BW	(1206)	1	±1, ±2, ±5	10 m to 100 m (E24)	10 mΩ ≤ R < 20 mΩ:0 to +200 20 mΩ ≤ R < 47 mΩ:0 to +150 47 mΩ ≤ R ≤ 100 mΩ:0 to +100	-55 to +155	Grade 0
ERJ6CW	(0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	-55 to +125	Grade 1
ERJ8CW	(1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-55 to +125	Grade 1

- (1) Use it on the condition that the case temperature is below the upper category temperature.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating x Resistance Value.
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

### Ratings

### <High power type>

Part (inch s	-	Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance <sup>(2)</sup> (%)	Resista Range (Ω)	(3)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade	
ERJ2BS	(0402)	0.166	±1, ±2, ±5	0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +300	-55 to +155	Grade 0	
ERJ2BQ	(0402)	0.100	11, 12, 13	0.22 to 1.0	(E24)	$0.22 \Omega \le R \le 1.0 \Omega : 0 \text{ to } +250$	33 (0 1133	Grade 0	
ERJ3BS	(0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +300			
ERJ3BQ	(0603)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$	-55 to +155	Grade 0	
EKJSBQ	(0003)	)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6DS	(0805)			0.10 to 0.20	(E24,E96)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +150			
ERJ6DQ	(0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1	(E24,E96)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +100$	-55 to +155	Grade 0	
LKJODQ	(0003)			0.22 to 3.1	(LZ+,LJO)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			
ERJ6BS	(0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +250			
ERJ6BQ	(0805)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0	
LKJUDQ	(0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$			
ERJ8BS	(1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +250			
ERJ8BQ	(1206)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0	
EKJODQ	(1200)	(0)		1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$			
ERJ14BS	(1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +200			
ERJ14BQ	(1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0	
EKJ14BQ	(1210)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) E96 series also have  $\pm 0.5$  %,  $\pm 1$  % line-up.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (3) Please contact us when resistors of irregular series are needed.

<Standard type>

Part (inch		Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range <sup>(2)</sup> (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJ3RS	(0603)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +300		
ERJ3RQ	(0603)	0.1	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$	-55 to +155	Grade 0
	()			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6RS	(0805)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +250		
ERJ6RQ	(0805)	0.125	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
LIGORQ	(0003)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ8RS	(1206)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +250		
ERJ8RQ	(1206)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
LIGORQ	(1200)	'		1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ14RS	(1210)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +200		
ERJ14RQ	(1210)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LICITING	(1210)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12RS	(1812)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +200		
ERJ12RQ	(1812)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIGIZIQ	(1012)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12ZS	(2010)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +200		
ERJ12ZQ	(2010)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LKJIZZQ	(2010)	<b>'</b>		1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ1TRS	(2512)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$ : 0 to +200		
ERJ1TRQ	(2512)	1	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0
LIGTING	(2312)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		

- (1) Use it on the condition that the case temperature is below the upper category temperature.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating} \times \text{Resistance Value}}$ .
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

### **Ratings**

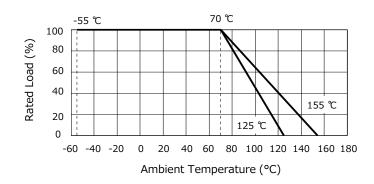
<Low TCR type>

Part (inch		Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range $^{(2)}$ $(\Omega)$	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJL03	(0603)	0.2	±1, ±5	47 m to 100 m	±200	-55 to +125	Grade 1
ERJL06	(0805)	0.25	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL08	(1206)	0.33	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL14	(1210)	0.33	±1, ±5	20 m to 100 m		-55 to +125	Grade 1
ERJL12	(1812)	0.5	±1, ±5	20 m to 100 m	$R < 47 \text{ m}\Omega : \pm 300$	-55 to +125	Grade 1
ERJL1D	(2010)	0.5	±1, ±5	40 m to 100 m	$R \ge 47 \text{ m}\Omega: \pm 100$	-55 to +125	Grade 1
ERJL1W	(2512)	1	±1, ±5	40 m to 100 m		-55 to +125	Grade 1

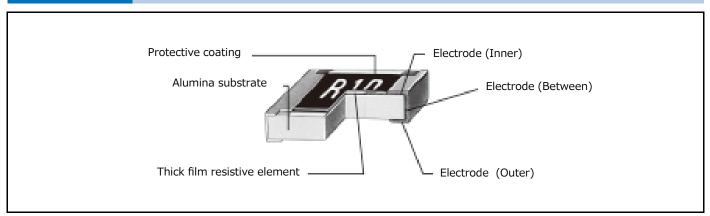
- (1) Use it on the condition that the case temperature is below the upper category temperature.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\( Power Rating \times Resistance Value. \)
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Standard R.V. : 20 m $\Omega$ , 22 m $\Omega$ , 33 m $\Omega$ , 39 m $\Omega$ , 47 m $\Omega$ , 50 m $\Omega$ , 100 m $\Omega$ , Custom R.V. : Each 1 m $\Omega$  within upper range.

### **Power Derating Curve**

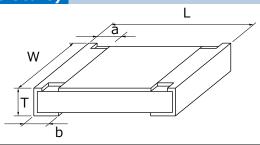
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



### Construction



### Dimensions in mm (not to scale)



Part No.			Dimensions (mm)			Mass (Weight)	
rait No.	L	W	a	b	Т	(g/1000pcs)	
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8	
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8	
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8	
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3	
ERJ3LW (10 m $\Omega$ ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3	
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6	
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6	
ERJ6CW (10 to 13 mΩ)	2.05±0.20	2.05±0.20 1.30±0.20		0.60±0.20	0.60±0.20	0.65±0.10	6
ERJ6CW (15 to 30 mΩ)		1.30±0.20	0.45±0.20	0.45±0.20	0.65±0.10		
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5	
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5	
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13	
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13	
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13	
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10	
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16	
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27	
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27	
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45	
ERJL1W	6.40±0.20	3.20±0.20	0.65±0.20	1.30±0.20	1.10±0.10	79	



### Performance

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
 High power (double-sided resistive elements structure) type>

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 C			
T. C. R.	Within Specified	+25 °C/+125 °C			
1. C. R.	T. C. R.	+25 °C/+125 °C			
		ERJ6LW : Rated Voltag× 1.77, 5 s			
Overload	±2 %	ERJ8BW (R > 0.05 $\Omega$ ) : Rated Voltag× 1.77, 5 s			
		Other : Rated Voltag× 2.0 , 5 s			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
David Change of Tanananahan	±1 %	-55 °C (30min.) / +155 °C (ERJ□LW, ERJ□CW : +125 °C)			
Rapid Change of Temperature	ERJ2LW: ±2 %	(30 min.), 100 cycles			
High Temperature Exposure	±1 %	+155 °C (ERJ□LW, ERJ□CW : +125 °C), 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life III Haiffidity	±3 %	1.5 h ON / 0.5 h OFF cycle , 1000 h			
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR
 High power type/Standard type>

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified	20 °C		
	Tolerance			
T. C. R.	Within Specified	+25 °C/+125 °C		
1. C. K.	T. C. R.	+23 C/+123 C		
Overload	±2 %	Rated Voltage× 2.5 (ERJ6D: ×1.77), 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life in Fidinialty	±3 /0	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

● ERJL03, L06, L08, L14, L12, L1D, L1W < Low TCR type >

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles
High Temperature Exposure	±1 %	+125 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity ±3 %		60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



### **Current Sensing Resistors, Metal Plate Type**

## **Current Sensing Resistors, Metal Plate Type**

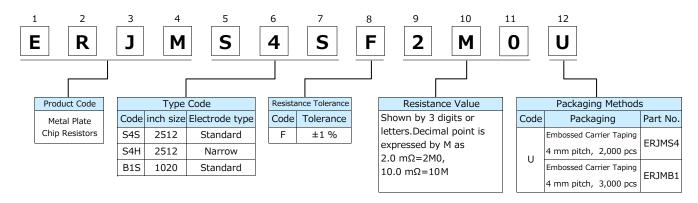
11

Series: ERJ MS4, MB1

### **Features**

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65  $^{\circ}$ C to +170  $^{\circ}$ C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**



### Ratings

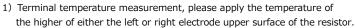
Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F: ±1	±75	-65 to +170	130	Grade 0
ERJMS4H	3	5, 6	F: ±1	±75	-65 to +170	130	Grade 0
(2512)	2	7, 8, 9, 10	F: ±1	±75	-65 to +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F: ±1	±75	-65 to +170	130	Grade 0

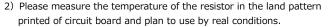
<sup>\*</sup> Please contact us when resistors of irregular series are needed.

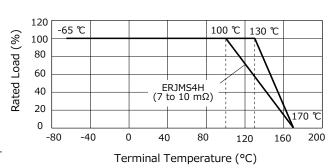
### **Power Derating Curve**

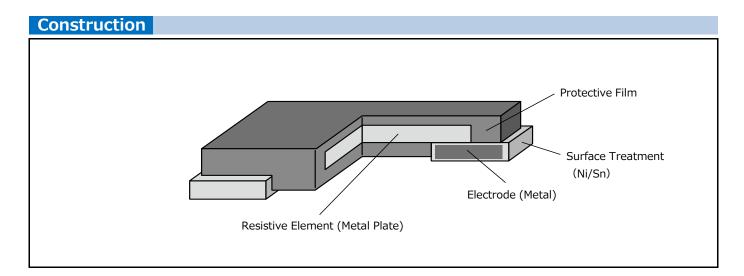
If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right. <Supplemented>

In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.





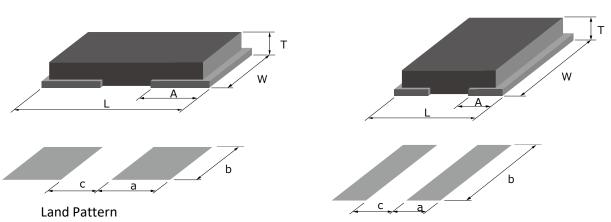




### Dimensions in mm (not to scale), Recommended Land Pattern



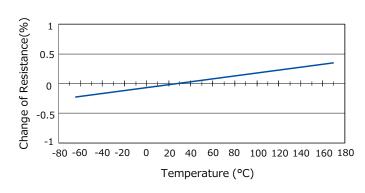


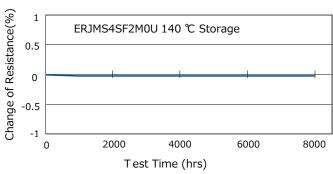


		Dimonsio	ons (mm)	Recomm	Mass			
Part No.		Difficisio	nis (iliili)			(mm)		(Weight)
	L	W	Α	Т	a	b	С	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40

### Typical Temp. dependence of electrical resistance

### **Long-term stability**





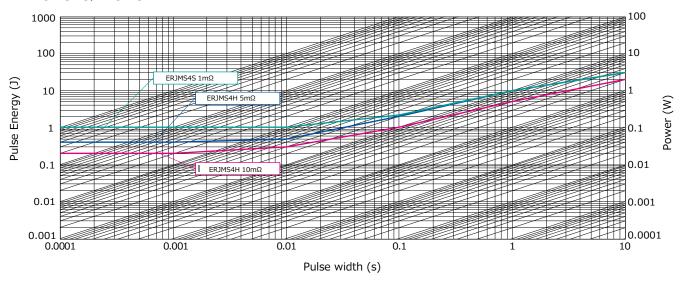
### Maximum pulse energy respectively pulse power for continuous operation

Referance Data

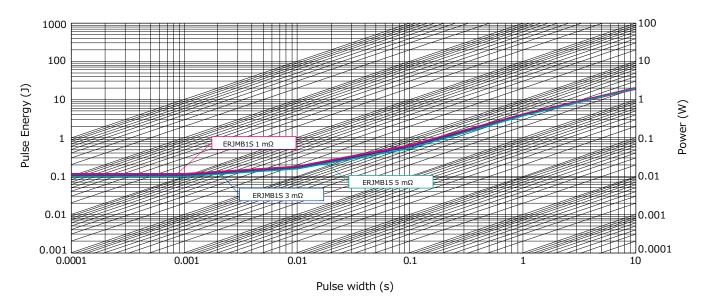
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance =  $\pm 1$  %

### ERJMS4S/ERJMS4H



#### • ERJMB1S



### Performance (AEC-Q200)

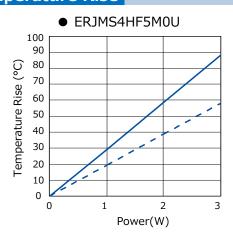
### • ERJMS4S/ERJMS4H

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.20 %	-55 °C / +155 °C, 1000 cycles
Overload	±0.5 %	0.10 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	−65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

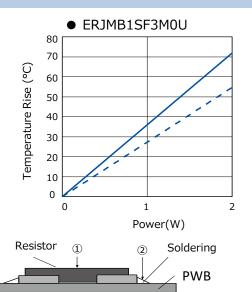
#### • ERJMB1

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.30 %	-55 °C / +155 °C, 1000 cycles
Overload	±1 %	0.30 %	Rated Power× 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	-65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

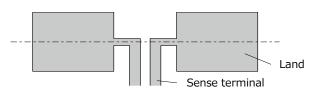
### Temperature Rise



① ---- <a href="#">Condition></a>
② ---- Base material : FR-4 (t 1.6 mm)
Copper Thickness : 70 µm, Two layer



### **Sense terminal-Layout**





### **High Power Chip Resistors / Wide Terminal Type**

## High Power Chip Resistors / Wide Terminal Type







Series: ERJ A1, B1, B2, B3

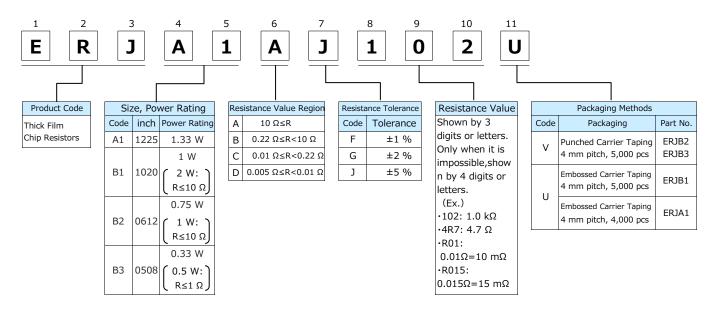
### **Features**

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

### **Recommended Applications**

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**



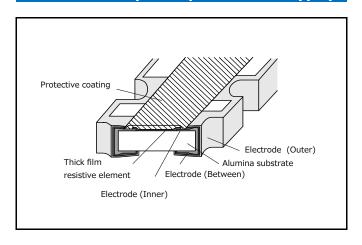


### **Ratings**

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resistanc Range (Ω)	e	T.C.R. (×10 <sup>-6</sup> /k		Category Temperature Range (℃)	AEC- Q200 Grade					
				±1	100 m to 10 k	(E24)	±100								
ERJA1 (1225)	1.33	200	400	±2, ±5	10 m to 10 k	(E24)	R<100mΩ	: ±350		Grade 0					
(1223)				±2, ±3	10 III to 10 k	(L24)	100mΩ≤R	: ±200							
							R< 22mΩ	: 0 to +350							
				±1	10 m to 10 k	(F24)	22mΩ ≤R< 47mΩ	: 0 to +200							
ERJB1	1			-1	10 III to 10 K	(LZ 1)	47mΩ ≤R<100mΩ	: 0 to +150							
(1020)	2(R ≤ 10 Ω)	200	400				100mΩ ≤R	: ±100		Grade 0					
(1020)	_(1031)						R< 22mΩ	: 0 to +350							
				±2, ±5	10 m to 10 k	(E24)	22mΩ ≤R<100mΩ	: 0 to +200							
							100mΩ ≤R	: ±200							
						R< 22mΩ	: 0 to +300								
							22mΩ ≤R< 47mΩ	: 0 to +200							
							±1	10 m to 1 M	(E24)	47mΩ ≤R<100mΩ	: 0 to +150	-55 to +155			
			400				100mΩ ≤R<220mΩ	: 0 to +100							
ERJB2	0.75	200		400	400	400	400	400				220mΩ ≤R	: ±100		Grade 0
(0612)	$1(R \le 10 \Omega)$	200						±2	10 m to 1 M	(E24)	R< 22mΩ	: 0 to +300		Grade 0	
					5 m, 6 m,		22mΩ ≤R< 47mΩ	: 0 to +200							
				±5	7 m 8 m	(E24)	47mΩ ≤R<100mΩ	: 0 to +150							
					9 m,	(LZ 1)	100mΩ ≤R<220mΩ	: 0 to +200							
					10 m to 1 M		220mΩ ≤R	: ±200							
							R< 47mΩ	: 0 to +300							
	33 0.33		±1	20 m to 10	(E24)	47mΩ ≤R< 1Ω	: 0 to +200								
ERJB3		200				1Ω ≤R	: ±100		Grade 0						
(0508)	$0.5(R \le 1 \Omega)$	150	150 200				R< 47mΩ	: 0 to +300		Grade 0					
				±2, ±5	20 m to 10	(E24)	47mΩ ≤R< 1Ω	: 0 to +200							
							1Ω ≤R	: ±200							

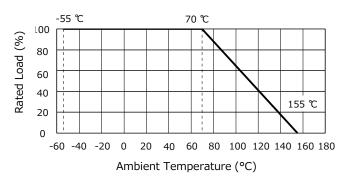
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{Power}$  Rating  $\times$  Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

### Construction (Example : ERJA1 type)



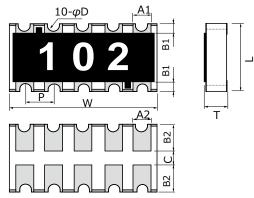
### **Power Derating Curve**

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

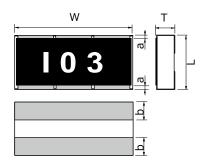




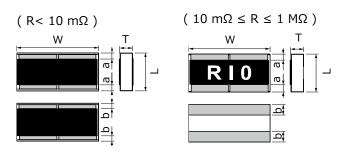
### Dimensions in mm (not to scale)



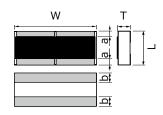
Part No.		Dimensions (mm)				
Part No.	L	W	Т	$A_1$	B <sub>1</sub>	(g/1000 pcs)
	3.20±0.20	6.40±0.20	0.55±0.10	0.70±0.20	0.45±0.20	
ERJA1	A <sub>2</sub>	B <sub>2</sub>	Р	<i>φ</i> D	С	40
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.	



Part No.		Dimensions (mm)					
Part No.	L	W	T	a	b	(g/1000 pcs)	
ERJB1	2.50±0.20	5.00±0.20	0.55±0.20	0.25±0.20	0.90±0.20	27	



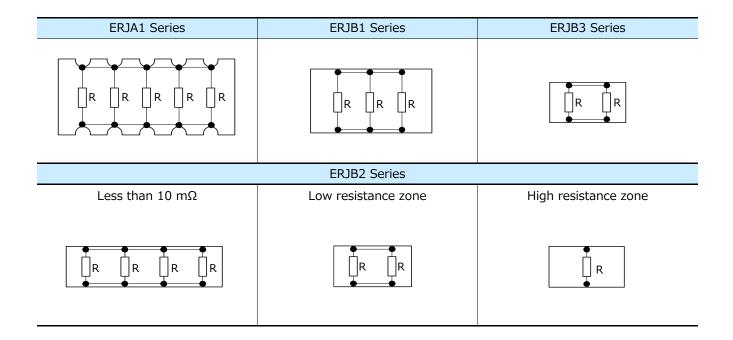
Part No.		Dimensions (mm)				
ERJB2	L	W	Т	а	b	(g/1000 pcs)
5 mΩ≤R< 10 mΩ			0.65±0.15	0.30±0.20	0.30±0.20	
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.55±0.15	0.30±0.20	0.50±0.20	11
220 mΩ≤R≤ 1 MΩ			0.55±0.15	0.25±0.20	0.50±0.20	



Part No.		Dimensions (mm)					
rait No.	L	W	Т	a	b	(g/1000 pcs)	
ERJB3	1.25±0.10	2.00±0.15	0.50±0.10	0.25±0.20	0.40±0.20	4.8	



### **Circuit Configuration**



### Performance

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	ERJA1, ERJB1 (R>10), ERJB3 (R>1) : Rated Voltag× 2.5 , 5 s ERJB2 (R>10) : Rated Voltag× 2.2 , 5 s ERJB1 (R $\leq$ 10), ERJB2 (R $\leq$ 10), ERJB3 (R $\leq$ 1): Rated Voltag× 2.0 , 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



## Low TCR High Power Chip Resistors / Wide Terminal Type

.010

.010

Series: ERJ D1, D2

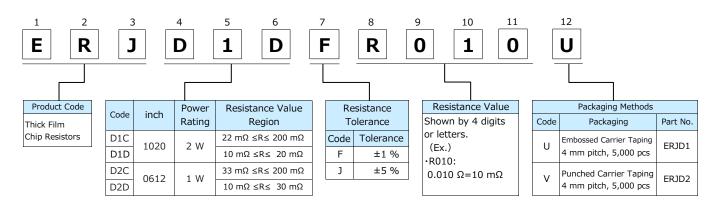
#### **Features**

- $\bullet$  Achieved High power and low TCR ( $\pm 100 \times 10^{-6}$ /K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

### **Recommended Applications**

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

### **Explanation of Part Numbers**



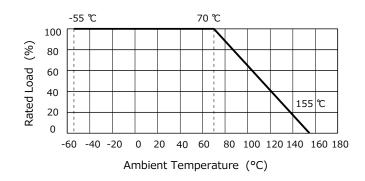
### Ratings

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100		

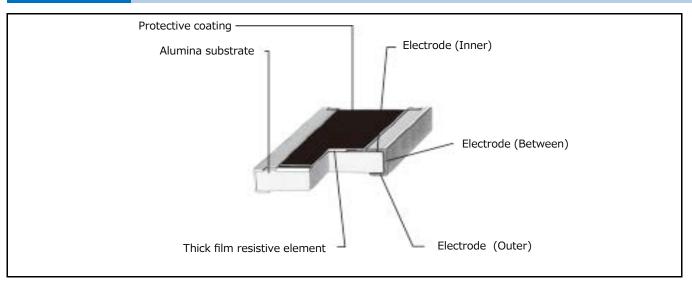
- (1) Use it on the condition that the case temperature is below the upper category temperature.
  - · Please contact us when resistors of irregular series are needed.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value.
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

#### **Power Derating Curve**

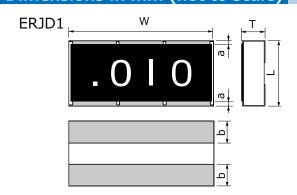
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

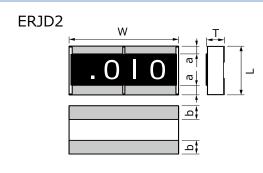


#### Construction



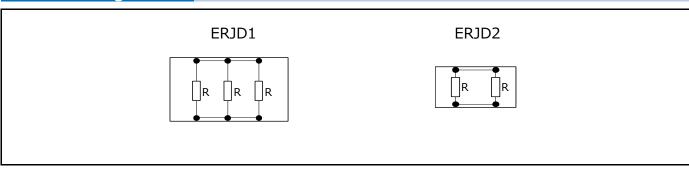
## Dimensions in mm (not to scale)





Part No.	Dimensions (mm)						
Part No.	L	W	Т	а	b	(g/1000 pcs)	
ERJD1	2.50±0.20	5.00±0.20	0.60±0.20	0.30±0.20	0.90±0.20	27	
ERJD2	1.60±0.15	3.20±0.20	0.65±0.15	0.30±0.20	0.50±0.20	11	

# **Circuit Configuration**





Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±2 %	Rated Voltag× 2.0 , 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity ±3 % 60 °C, 90 % to 95 %RH, Rated Voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h		60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



# **Anti-Surge Thick Film Chip Resistors**

# **Anti-Surge Thick Film Chip Resistors**



Series: ERJ PA2, P03, PA3, P06, P08, P14

#### **Features**

- ESD surge characteristics superior to standard metal film resistors
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power… 0.20 W: 0402 inch / 1005 mm size (ERJPA2), 0603 inch / 1608 mm size (ERJP03)

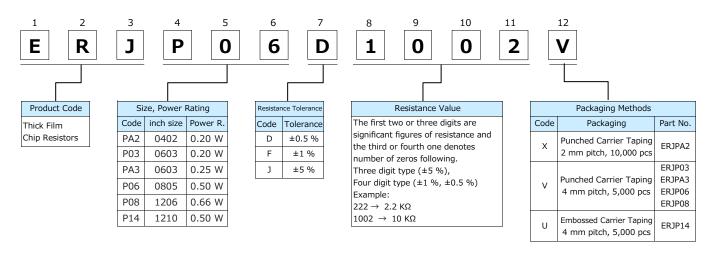
0.25 W: 0603 inch / 1608 mm size (ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**

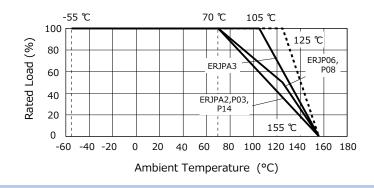


Rat	Ratings Rating									
Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Ra	stance nge Ω)		C.R. O <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC-Q200 Grade
ERJPA2 (0402)	0.20	50	100	±0.5, ±1	10 to 1 M 10 to 1 M	(E24, E96) (E24)		200		Grade 1
				±0.5	10 to 1 M	(E24, E96)	±	150		
ERJP03	0.20	150	200	±1	10 to 1 M	(E24, E96)	±2	200		C d - 0
(0603)	0.20	150	200	±5	1 to 1 M	(524)	R<10Ω	: -150 to +400		Grade 0
				Ξ5	1 10 1 14	(E24)	10Ω≤R	: ±200		
ERJPA3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±	100		Grade 0
(0603)	(105 ℃)	130	200	±5	1 to 1.5 M	(E24)	±2	200		Grade 0
				±0.5 ±1	10 to 1 M	(E24, E96)	R<33Ω	: ±300		
ERJP06				-0.0, -1		( :, : )	33Ω≤R	: ±100	-55 ~ +155	
(0805)	0.50	400	600				R<10Ω	: -100 to +600		Grade 0
, ,				±5	1 to 3.3 M	(E24)	10Ω≤R<33Ω	: ±300		
							33Ω≤R	: ±200		
ERJP08				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		
(1206)	0.66	500	1000	±5	1 to 10 M	(E24)	R<10Ω	: -100 to +600		Grade 0
					1 00 10	(== .)	10Ω≤R	: ±200		
ERJP14				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		
(1210)	0.50	200	400	±5	1 to 1 M	(E24)	R<10Ω	: -100 to +600		Grade 0
(1210)						(-21)	10Ω≤R	: ±200		

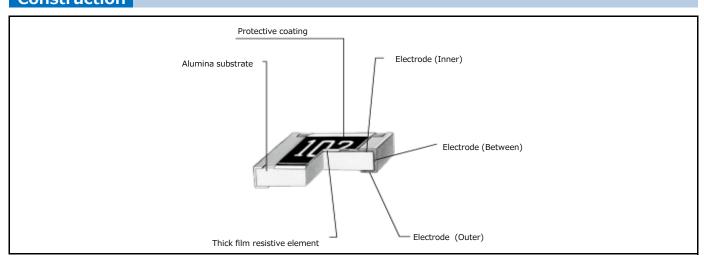
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance)  $\times$  RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Power Derating Curve**

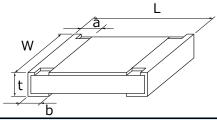
For resistors operated in rated temperatures above 70 °C or 105 °C, power rating shall be derated in accordance with the figure on the right. \* When the temperature of ERJP14 is 155 °C or less, the derating start temperature can be changed to 125 °C. (See the dotted line)



#### Construction

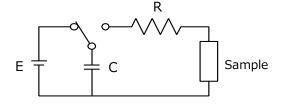


#### **Dimensions in mm (not to scale)**



Part No.	Dimensions (mm)						
rarervor	L W		а	b	t	(g/1000 pcs)	
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.05	0.35±0.05	0.8	
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2	
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJP08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16	

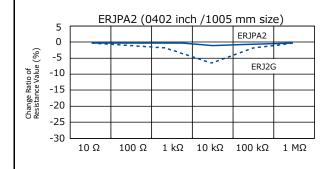
#### **ESD Characteristic**

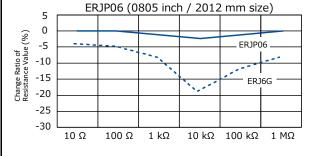


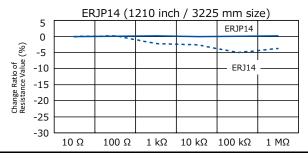
Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω( $\leq$ 1.5 kΩ) / 150 Ω( $>$ 1.5 kΩ)
С	100 pF	150 pF
Е	±1 kV	±3 kV

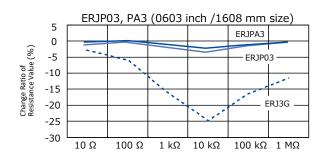
Anti-Surge Thick Film Chip Resistors (ERJP Series)

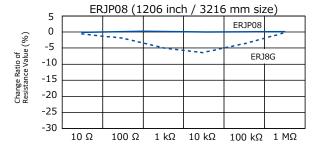
Thick Film Chip Resistors (ERJ Series)











%This data is for reference purposes.
Please check with the actual equipment before use.



# **Anti-Surge Thick Film Chip Resistors**

Test Item	Performance Requirements ∠R	Test Conditions			
Resistance	Within Specified Tolerance	20 °C			
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C (ERJPA2 : +125 °C)			
	12.00	ERJP06 : Rated Voltag× 1.77, 5 s			
Overload	$\pm 2\%$ Only when it is ERJP03 (D), P14 (D): $\pm 0.5\%$	ERJPA2, ERJPA3, ERJP08: Rated Voltag× 2.0, 5 s			
	Only When it is then 63 (5), 111 (5) : ±6.3 %	ERJP03, ERJP14 : Rated Voltag× 2.5 , 5 s			
Resistance to	D: ±0.5 %, F, J: ±1 %	270 °C, 10 s			
Soldering Heat	2.1 = 0.13 767 1731 = 1 76				
Rapid Change of	±1 %	-55 °C (30min.) / +155 °C (ERJPA2 : +125 °C) (30min.),			
Temperature	-	100 cycles			
High Temperature	±1 %	+155 °C, 1000 h			
Exposure	-1 /3	1133 6, 1000 11			
Damp Heat, Steady	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
State	/V	00 C, 90 % to 93 % till, 1000 ff			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life in Fidinialty	Only when it is ERJP03 (D), P14 (D): ±1 %	1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±3 %	70 °C (ERJPA3 : +105 °C), Rated Voltage,			
(ERJPA3 : 105 °C)	Only when it is ERJP03 (D), P14 (D) : $\pm 1$ %	1.5 h ON / 0.5 h OFF cycle, 1000 h			



# **Anti-Pulse Thick Film Chip Resistors**

# **Anti-Pulse Thick Film Chip Resistors**









Series: ERJ T06, T08, T14

ERJ T14L

#### **Features**

Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)

- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability ..... Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power ........ 0.25 W: 0805 inch /2012 mm size (ERJT06)

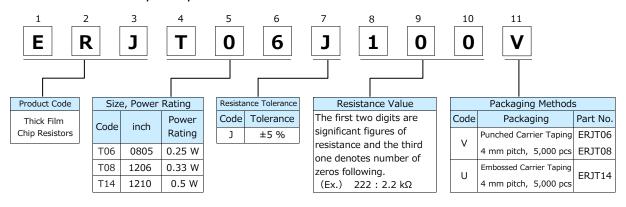
0.33 W: 1206 inch /3216 mm size (ERJT08)

0.50 W: 1210 inch /3225 mm size (ERJT14, ERJT14L)

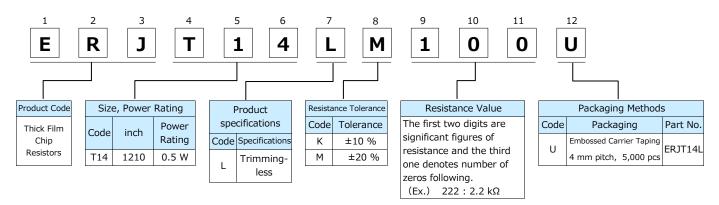
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**

• Series ERJT06, T08, T14



Series ERJT14L



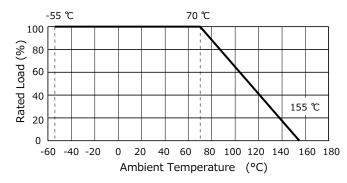
\* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Rat	Ratings								
Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade	
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 $\Omega$ : -100 to +600 10 $\Omega \le R < 33 \Omega$ : ±300 33 $\Omega \le R$ : ±200	-55 to +155	Grade 0	
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : $\pm$ 200	-55 to +155	Grade 0	
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : $\pm$ 200	-55 to +155	Grade 0	
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω : -100 to +600 10 Ω≤R : $\pm 200$	-55 to +155	Grade 0	

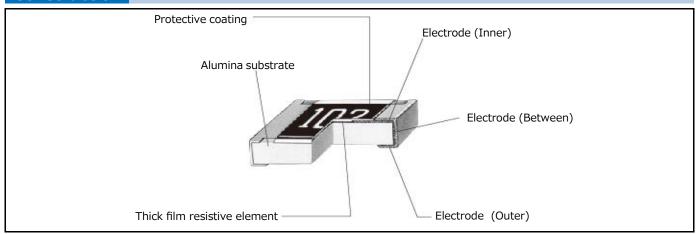
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Power Derating Curve**

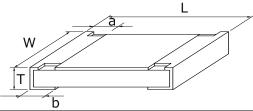
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



#### Construction



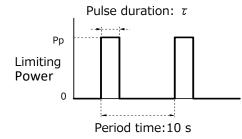
#### Dimensions in mm (not to scale)



Dart No.		Dimensions (mm)							
Part No.	L	W	a	b	Т	(g/1000 pcs)			
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

#### **Limiting Power Curve**

• In rush pulse Characteristic



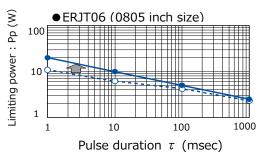
Test cycle: 1000 cycles

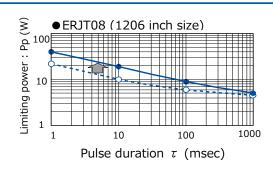
Spec : Resistance value = within  $\pm 5\%$ 

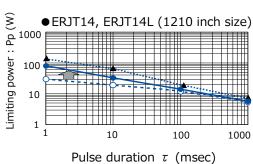
▲ : Anti-Pulse Thick Film Chip Resistors (Series ERJT14L)

• : Anti-Pulse Thick Film Chip Resistors (Series ERJT)

 $\bigcirc$ : Thick Film Chip Resistors (Series ERJ : 1  $\Omega$ )







- \*\*This data is for reference purposes.
  Please check with the actual equipment before use.
- ※ Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R. Within Specif		+25 °C/+155 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C±3 °C, 10 s ±1 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C ±2 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C ±2 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C ±2 °C, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h

# Panasonic INDUSTRY

# **Anti-Sulfurated Thick Film Chip Resistors**

# **Anti-Sulfurated Thick Film Chip Resistors**

# 102 102 102

# **ERJ S (Au-based inner electrode type)**

Series: ERJ S02, S03, S06, S08, S14, S12, S1D, S1T

# ERJ U (Ag-Pd-based inner electrode type)

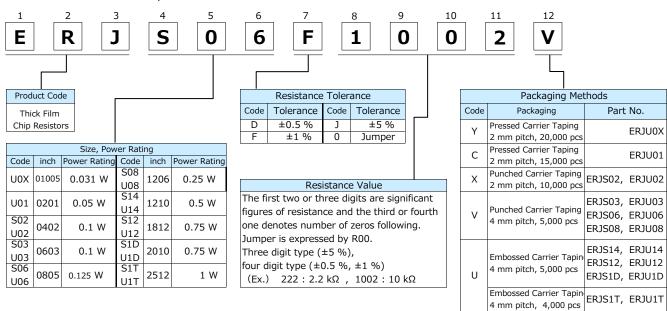
Series: ERJ U0X, U01, U02, U03, U06, U08, U14, U12, U1D, U1T, U6S, U6Q

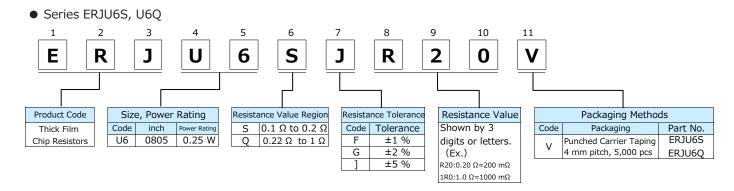
#### **Features**

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Ag-Pd-based inner electrode (Series ERJU )
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- ullet Low Resistance type ... Series ERJU6S, U6Q : 0.1  $\Omega$  to 1  $\Omega$
- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**

Series ERJS02 to ERJS1T, ERJU0X to ERJU1T





Rat	Ratings								
Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Ra	stance nge Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJU0X (01005)	0.031	15	30	±1 ±5	10 to 1 M	(E24, E96) (E24)	R<10 Ω : -100 to +600 10 Ω≤R<100 Ω : ±300 100 Ω≤R : ±200	-55 to +125	-
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1 M 1 to 1 M	(E24, E96) (E24)	R<10 Ω: -100 to +600	-55 to +125	-
ERJS02 ERJU02 (0402)	0.1	50	100	±0.5, ±1 ±5	1 to 1 M 1 to 3.3 M	(E24, E96) (E24)	10 $\Omega$ to 1 M $\Omega$ : ±200 1 M $\Omega$ <r :<br="">-400 to +150</r>	-55 to +155	Grade 0
ERJS03 ERJU03 (0603)	0.1	75	150	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0
ERJS06 ERJU06 (0805)	0.125	150	200	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	R<10 Ω:	-55 to +155	Grade 0
ERJS08 ERJU08 (1206)	0.25	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	· ·	-55 to +155	Grade 0
ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	10 $\Omega$ to 1 M $\Omega$ : ±200 (± 5 %) ±100 (±0.5 %, ±1 %)	-55 to +155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	1 MΩ <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	-400 to +150	-55 to +155	Grade 0
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

(2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$ , or Limiting Element Voltage listed above, whichever less.

(3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **[Low Resistance type]**

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range (Ω)		T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJU6S (0805)	0.25	±1, ±2, ±5	0.1 to 0.2	(E24)	0 to +150	-55 to +155	Grade 0
ERJU6Q (0805)	0.23	11, 12, 13	0.22 to 1	(E24)	0 10 +130	-33 to +133	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

- Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating} \times \text{Resistance Value.}}$
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

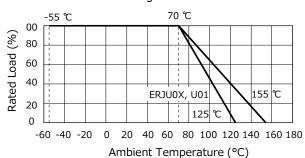
[For Jumper]

ror Jumpe	er <u>j</u>			
Part No.	Resistance( $\Omega$ )	Rated Current(A)	Maximum Overload Current (A) <sup>(1)</sup>	
ERJU0X		0.5	1	
ERJU01		0.5	1	
ERJS02 ERJU02		1	2	
ERJS03 ERJU03		1		
ERJS06 ERJU06	100 mΩ or less			
ERJS08 ERJU08	100 11132 01 1033			
ERJS14 ERJU14		2	4	
ERJS12 ERJU12		2	7	
ERJS1D ERJU1D				
ERJS1T ERJU1T				

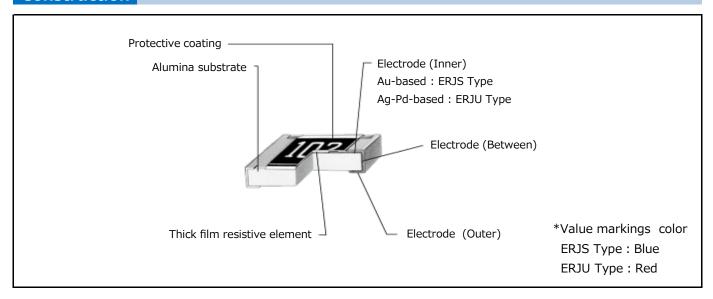
(1) Overload test current

#### **Power Derating Curve**

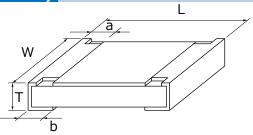
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



#### Construction



# Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
rait No.	L	W	a	b	T	(g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

## Performance

#### • Series ERJS02 to ERJS1T, ERJU0X to ERJU1T

Test Item	Performance Re	equirements ⊿R	Test Conditions		
rest item	Resistor type	Jumper type	rest conditions		
Resistance	Within Specified	100 mΩ or less	20 °C		
Resistance	Tolerance	100 11132 01 1655	20 °C		
T. C. R.	Within Specified	200 mΩ or less	+25 °C/+155 °C (ERJU0X,U01 : +25 °C/+125 °C)		
	T. C. R.	200 1132 01 1033	+23 C/+133 C (LIGOUX,001 : +23 C/+123 C)		
Overload	±2 %	100 mΩ or less	Rated Voltage× 2.5, 5 s		
Overload	12 /0	100 11132 01 1633	Jumper type: Max. Overload Current, 5 s		
Resistance to	±1 %	100 mΩ or less	270.00 10.0		
Soldering Heat	<b>1</b> 1 70	100 11132 01 1655	270 °C, 10 s		
Rapid Change of	±1 %	100 mΩ or less	−55 °C (30min.)/+155 °C (ERJU0X,U01 : +125 °C)		
Temperature	<u> </u>	100 1112 01 1622	(30min.), 100 cycles		
High Temperature	±1 %	100 mΩ or less	11EE 9C (ED]HOV HO1 13E 9C) 1000 b		
Exposure	<b>1</b> 1 70	100 11132 01 1655	+155 °C (ERJU0X,U01 : +125 °C), 1000 h		
Damp Heat, Steady	±1 %	100 mΩ or less	60 °C, 90 % to 95 %RH, 1000 h		
State	±1 /0	100 1132 01 1033	00° C, 90° 70 to 95° 701011, 1000 11		
Load Life in Humidity	±3 %	100 mΩ or less	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type:		
Load Life in Flaminity	15 70	100 11132 01 1633	Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±2.0/.	100 mΩ or less	70 °C, Rated Voltage (Jumper type :Rated Current),		
Endurance at 70 °C	±3 %	TOO HIS OF IESS	1.5 h ON / 0.5 h OFF cycle, 1000 h		

#### • Series ERJU6S, U6Q

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±1 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C(30min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



#### Anti-Sulfurated Thick Film Chip Resistors/Precision Type

# Anti-Sulfurated Thick Film Chip Resistors / Precision Type







Series: ERJ U2R, U3R, U6R

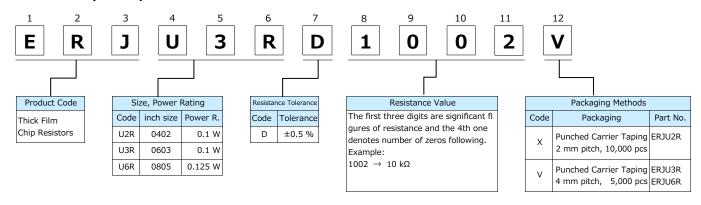
(Ag-Pd-based inner electrode type)

#### **Features**

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- ◆ High precision ··· Resistance tolerance : ±0.5 %, TCR : ±50 ×10<sup>-6</sup>/K
- High reliability ··· Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**

ERJU2R, U3R, U6R Series



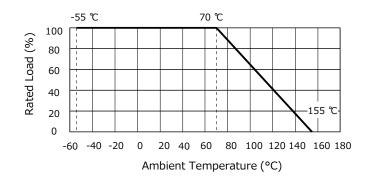
#### **Ratings**

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJU2R	0.1	50	100	±0.5	100 to 100 k		-55 to +155	Grade 0
(0402)					(E24, E96)			
ERJU3R	0.1	50	100	±0.5	100 to 100 k	±50	-55 to +155	Grade 0
(0603)	603) 0.1 50 10	100	10.5	(E24, E96)	±30	-55 to +155	Graue 0	
ERJU6R	0.125	150	200	±0.5	100 to 100 k		_55 to ±155	Grado 0
(0805)	0.123	150	200	±0.5	(E24, E96)		-55 to +155	Grade 0

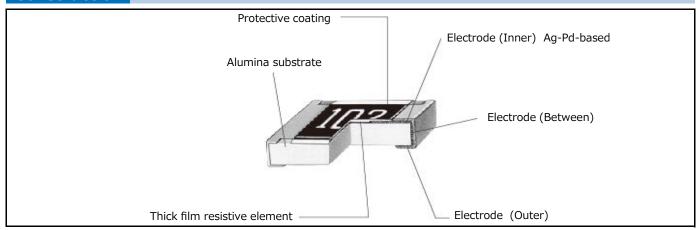
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Power Derating Curve**

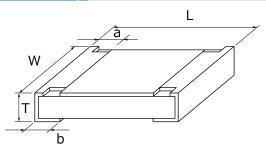
For resistors operated in ambient temperatures above 70  $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



#### Construction



#### Dimensions in mm (not to scale)



Part No.	Dimensions (mm)							
Part No.	L	W	a	b	Т	(g/1000 pcs)		
ERJU2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8		
ERJU3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2		
ERJU6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4		

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C		
Overload	±2 %	Rated Voltage × 2.5, 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C(30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life III Hulfilalty	12 70	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±2 %	70 °C, , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



# Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

102

Series: ERJ UP3, UP6, UP8

#### **Features**

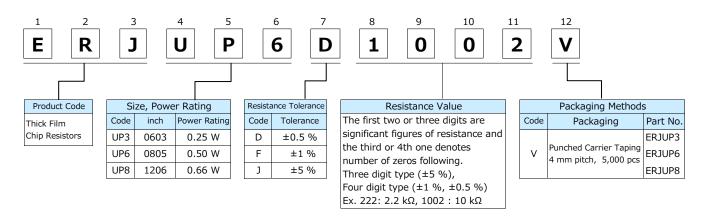
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability... Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power ..... 0.25 W: 0603 inch / 1608 mm size (ERJUP3)

0.50 W: 0805 inch / 2012 mm size (ERJUP6)

0.66 W: 1206 inch / 3216 mm size (ERJUP8)

- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**



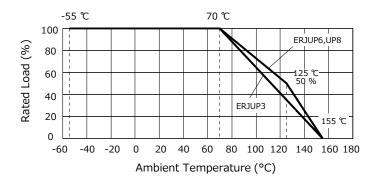
#### **Ratings**

Part No. (inch size)	Power Rating <sup>(1)</sup> at 70 °C (W)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC-Q200 Grade
ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
(0603)	0.23	150	200	±5	1 to 1.5 M (E24)	±200	-55 to +155	Grade 0
ERJUP6	EDIUDG			±0.5, ±1	10 to 1 M (E24, E96)	±100		
(0805)	0.50	400	600	±5	1 to 3.3 M (E24)	R<10 $\Omega$ : -100 to +600	-55 to +155	Grade 0
(0003)			±3	1 to 3.3 M (E24)	10 Ω≤R : ±200			
ED 11 IDO				±0.5, ±1	10 to 1 M (E24, E96)	±100		
ERJUP8 0.66		500	1000	±5	1 to 10 M (E24)	R<10 $\Omega$ : -100 to +600	-55 to +155	Grade 0
				±3	1 to 10 M (E24)	10 Ω≤R : ±200		

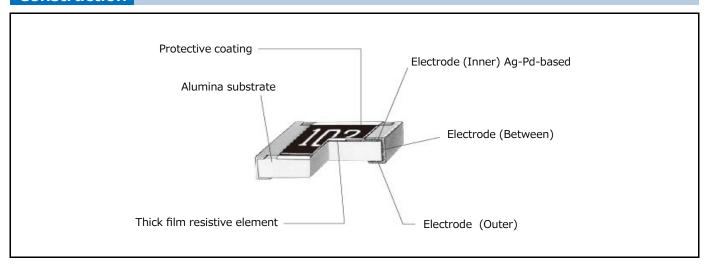
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Power Derating Curve**

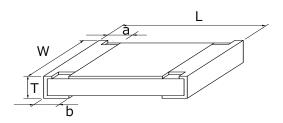
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



#### Construction



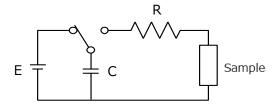
## Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
Part No.	L	W	а	b	Т	(g/1000 pcs)			
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			

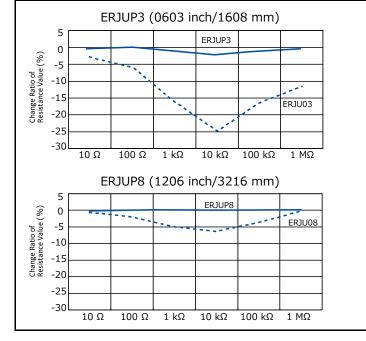


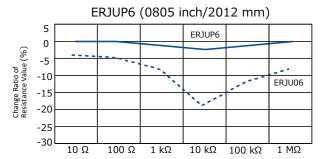
#### **ESD Characteristic**



R	R=0 Ω( $\leq$ 1.5 kΩ) / 150 Ω( $>$ 1.5 kΩ)
С	150 pF
Е	±3 kV

Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type (ERJUP Type) Anti-Sulfurated Thick Film Chip Resistors (ERJU Type)





%This data is for reference purposes.
Please check with the actual equipment before use.

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C		
Overload	±2 %	ERJUP6 : Rated Voltag× 1.77, 5 s ERJUP3, ERJUP8 : Rated Voltag× 2.0 , 5 s		
Resistance to Soldering Heat	D: ±0.5 %, F, J: ±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % ~ 95 %RH, 1000 h		
Load Life in Humidity	±3 %	60 °C, 90 % ~ 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



# Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

ROI

Series: ERJ C1

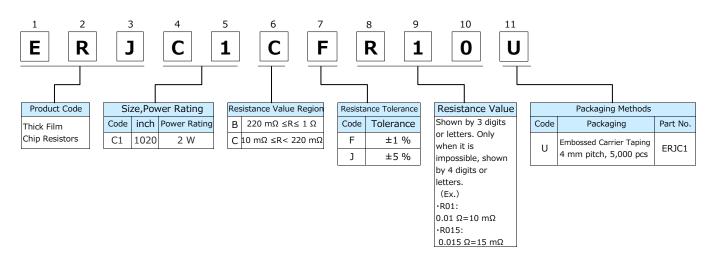
#### **Features**

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

#### **Recommended Applications**

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**



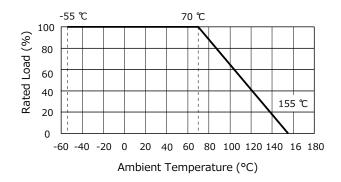
#### Ratings

Part No. (inch size)	Power Rating at 70 °C <sup>(1)</sup> (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)		Category Temperature Range (℃)	AEC- Q200 Grade
ERJC1 (1020)	2	±1	10 m to 1 (E24)	$10 \text{ m}\Omega \le R < 22 \text{ m}\Omega : 0$ $22 \text{ m}\Omega \le R < 47 \text{ m}\Omega : 0$ $47 \text{ m}\Omega \le R < 100 \text{ m}\Omega : 0$ $100 \text{ m}\Omega \le R \le 1 \Omega : 0$	0 to +200 0 to +150		Grade 0
(1020)		±5		$10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega : 0$ $22 \text{ m}\Omega \leq R < 100 \text{ m}\Omega : 0$ $100 \text{ m}\Omega \leq R \leq 1 \Omega : 0$			

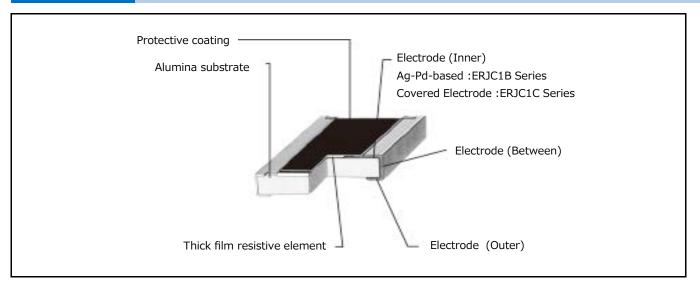
- (1) Use it on the condition that the case temperature is below the upper category temperature.
  - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
  - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

#### **Power Derating Curve**

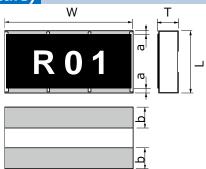
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



#### Construction

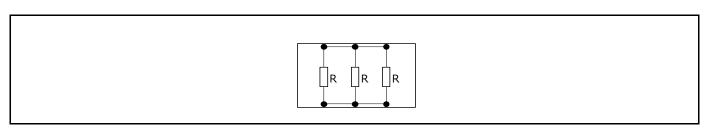


#### Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
Part No.	L	W	Т	a	b	(g/1000 pcs)			
ERJC1B	2 50+0 20	E 00±0 30	0 55+0 30	0.35±0.20	0.00+0.30	27			
ERJC1C 2.50±0.20	5.00±0.20	0.55±0.20	0.60±0.20	0.90±0.20	27				

# **Circuit Configuration**





Test Item	Performance Requirements ⊿	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload ±2 °		Rated Voltage× 2.0, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



# **Chip Resistors Array**

# **Chip Resistors Array**

Series: EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V



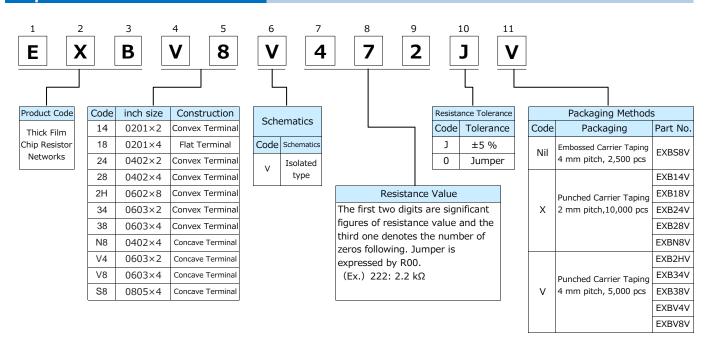
#### **Features**

- High density
  - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
  - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size: EXB18V
  - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
  - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
  - 8 resistors in 3.8 mm  $\times$  1.6 mm size / 1506 inch size : EXB2HV
  - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
  - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size: EXB38V, V8V
  - 4 resistors in 5.1 mm  $\times$  2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**



#### **Ratings**

#### [For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage <sup>(1)</sup> (V)	Maximum Overload Voltage <sup>(2)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (°C)	AEC- Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	10 Ω to 1 MΩ:	-55 to +125	Grade 1
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)	±200	-55 to +125	-
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)		-55 to +125	-

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$ , or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

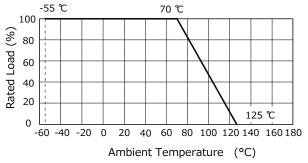
#### [For Jumper]

Part No.	Resistance( $\Omega$ )	Rated Current (A / element)	Maximum Overload Current (A) <sup>(1)</sup>
EXB14V		0.5	1
EXB18V		0.5	1
EXB24V		1	2
EXB28V		1	2
EXB2HV		1	
EXB34V	50 m $\Omega$ or less	1	2
EXB38V		1	2
EXBN8V		1	2
EXBV4V		1	2
EXBV8V		1	2
EXBS8V		2	4

(1) Overload test current

#### **Power Derating Curve**

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

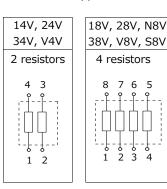


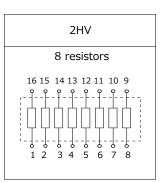
#### Construction(Example : Concave Terminal)

# Protective coating Alumina substrate Electrode (Outer) Thick film resistive Electrode (Inner)

#### **Schematics**

#### Isolated type

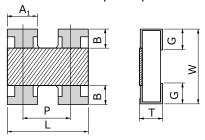


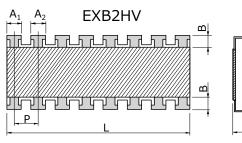


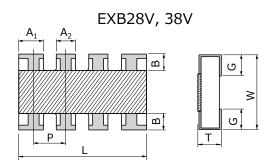
## Dimensions in mm (not to scale)

#### (1) Convex Terminal type

EXB14V, 24V, 34V







Part No.		Dimensions (mm)											
(inch size)	L	W	Т	A <sub>1</sub>	A <sub>2</sub>	В	Р	G	(g/1000 pcs)				
EXB14V (0603X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5				
EXB24V (1005×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2				
EXB28V (1005×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0				
EXB2HV (1605×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0				
EXB34V (1608×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5				
EXB38V (1608×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0				

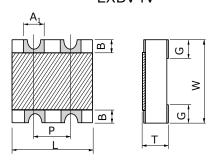
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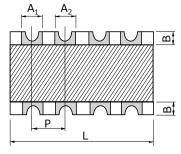
( ) Reference

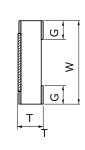
#### (2) Concave Terminal type

EXBV4V



# EXBN8V, V8V, S8V

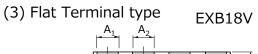


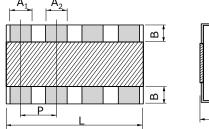


Part No.		Dimensions (mm)										
(inch size)	L	W	Т	$A_1$	$A_2$	В	Р	G	(g/1000 pcs)			
EXBN8V (1005×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0			
EXBV4V	1.60	1.60	0.60±0.10	.60±0.10 0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0			
(1608×2)	+0.20/-0.10	+0.20/-0.10	0.0010.10									
EXBV8V	3.20	1.60	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10			
(1608×4)	+0.20/-0.10	+0.20/-0.10	0.0010.10	0.0010.10	0.0010.10	0.30±0.13	(0.80)					
EXBS8V	5.08	2.20	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30			
(2012×4)	+0.20/-0.10	+0.20/-0.10	0.70±0.20	0.00±0.13	0.00±0.13	0.30±0.13	(1.27)	0.55±0.15	30			

( ) Reference

## Dimensions in mm (not to scale)





Part No.		Dimensions (mm)									
(inch size	L	W	Т	A <sub>1</sub>	A <sub>2</sub>	В	Р	G	(g/1000 pcs)		
EXB18V	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0		

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Test Item	Performance Requirements ⊿R	Test Conditions					
Resistance	Within Specified Tolerance	20 °C					
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C					
Overload	±2 %	lated Voltage× 2.5, 5 s umper type : Max. Overload Current, 5 s					
Resistance to Soldering Heat	±1 %	270 °C, 10 s					
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles					
High Temperature Exposure	±1 %	+125 °C, 1000 h					
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h					
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					
Endurance at 70 °C	±3 %	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					



# **Anti-Sulfurated Chip Resistors Array**

# Anti-Sulfurated Chip Resistors Array



Series: EXB U14, U18, U24,

U28, U2H, U34, U38

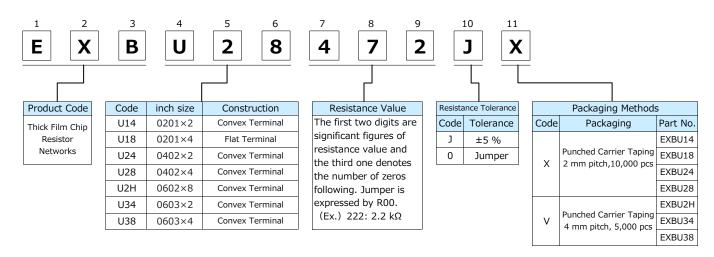
#### **Features**

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
  - 2 resistors in 0.8 mm  $\times$  0.6 mm size / 0302 inch size : EXBU14
  - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
  - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
  - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
  - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
  - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
  - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**



## Ratings

#### [For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage <sup>(1)</sup> (V)	Maximum Overload Voltage <sup>(2)</sup> (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	-
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	10 $\Omega$ to 1 M $\Omega$ : ±200	-55 to +125	Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$ , or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

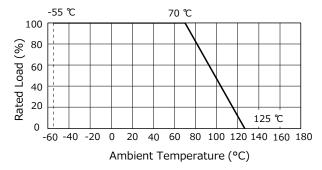
#### [For Jumper]

Part No.	Resistance( $\Omega$ )	Rated Current (A / element)	Maximum Overload Current (A) <sup>(1)</sup>		
EXBU24					
EXBU28					
EXBU2H	100 m $\Omega$ or less	1	2		
EXBU34					
EXBU38					

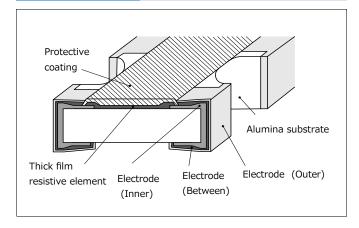
(1) Overload test current

#### **Power Derating Curve**

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

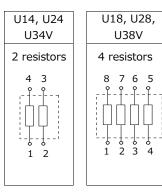


#### Construction



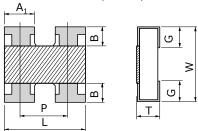
#### **Schematics**

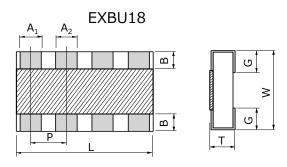
#### Isolated type

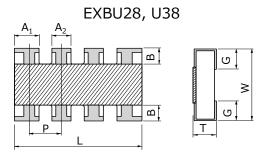


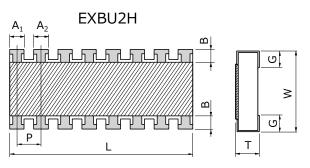
# Dimensions in mm (not to scale)











Part No.	Dimensions (mm)									
(inch size)	L	W	Т	A <sub>1</sub>	A <sub>2</sub>	В	Р	G	(g/1000 pcs)	
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5	
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0	
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2	
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0	
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0	
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5	
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0	

Test Item	Performance Requirements ⊿R	Test Conditions					
Resistance	Within Specified Tolerance	20 °C					
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C					
Overload	±2 %	Rated Voltage× 2.5, 5 s  Jumper type: Max. Overload Current, 5 s					
Resistance to Soldering Heat	±1 %	270 °C, 10 s					
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles					
High Temperature Exposure	±1 %	+125 °C, 1000 h					
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h					
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type: Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					
Endurance at 70 °C	±3 %	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					

# **Chip Resistors Networks**

# **Chip Resistors Networks**

102 102 = 12

Series: EXB D, E, A, Q

#### **Features**

- High density placing for digital signal circuits
  - ·Bussed 8 or 15 resistors for pull up/down circuits

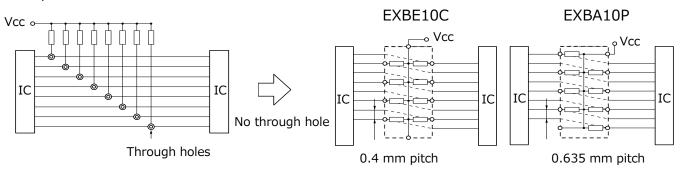
EXBD :  $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$ , 0.635 mm pitch EXBE :  $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$ , 0.8 mm pitch EXBA :  $6.4 \text{ mm} \times 3.1 \text{ mm} \times 0.55 \text{ mm}$ , 1.27 mm pitch EXBQ :  $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}$ , 0.5 mm pitch

- •Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

#### (High density placing)

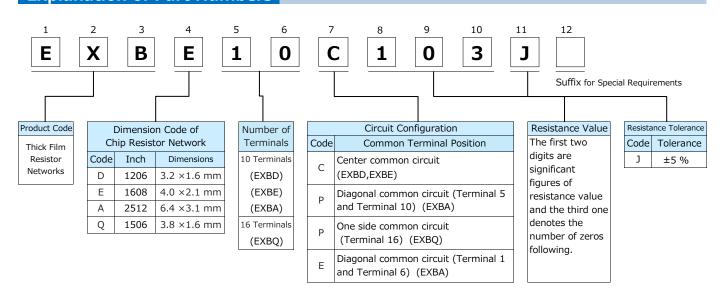
Pull up resistors

Direct placement on the bus line



■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**

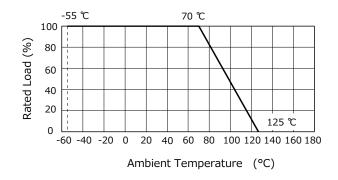


Rati	Ratings Rating										
Part No. (inch size)	Resistance Range (Ω)	Resistance Tolerance (%)	Number of Terminals	Number of Resistors	Power Rating <sup>(1)</sup> at 70 °C (W/element)	Limiting Element Voltage <sup>(2)</sup> (V)	Maximum Overload Voltage <sup>(3)</sup> (V)	T.C.R. (×10 <sup>-6</sup> /K)	Category Temperature Range (℃)	AEC- Q200 Grade	
EXBD (1206)			10 terminals	8 element	0.05 / element	25	50	±200	-55 to +125	-	
EXBE (1608)	47 to 1 M (E12)	±5			0.063 / element	25	50	±200	-55 to +125	-	
EXBA (2512)					0.063 / element	50	100	±200	-55 to +125	-	
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200	-55 to +125	-	

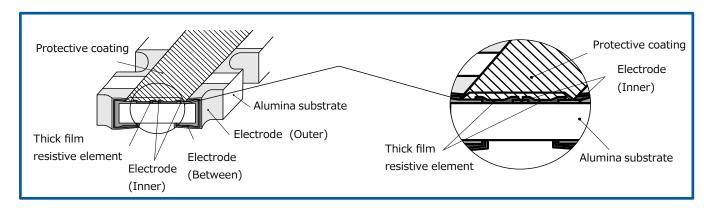
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$ , or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

#### **Power Derating Curve**

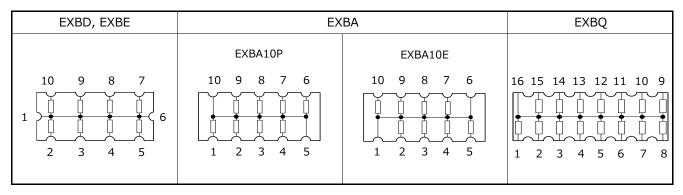
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



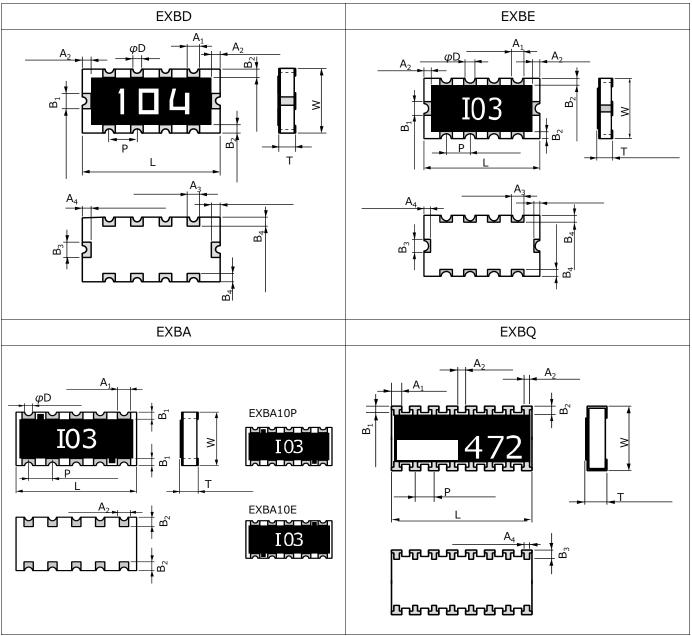
#### Construction(Example : EXBD)



#### **Circuit Configuration**



## **Dimensions in mm (not to scale)**



			Di	mensions (mi	m)			Mass (Weight)			
Part No.	L	W	Т	A <sub>1</sub>	A <sub>2</sub>	B <sub>1</sub>	B <sub>2</sub>	(g/1000 pcs)			
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1	. ,			
EXBD	A <sub>3</sub>	$A_4$	B <sub>3</sub>	B <sub>4</sub>	Р	φD		10			
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1					
			Di	mensions (mi	n)			Mass (Weight)			
Part No.	L	W	Т	A <sub>1</sub>	A <sub>2</sub>	B <sub>1</sub>	B <sub>2</sub>	(g/1000 pcs)			
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20				
EXBE	A <sub>3</sub>	$A_4$	B <sub>3</sub>	B <sub>4</sub>	Р	φD		16			
	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2					
	Dimensions (mm)										
Part No.	L	W	T	A <sub>1</sub>	B <sub>1</sub>	A <sub>2</sub>	B <sub>2</sub>	Mass (Weight) (g/1000 pcs)			
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20				
EXBA	Р	φD						40			
	1.27±0.10	0.3+0.1/-0.2									
			Di	mensions (mi	n)			Mass (Weight)			
Part No.	L	W	T	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	B <sub>1</sub>	(g/1000 pcs)			
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05				
EXBQ	B <sub>2</sub>	$A_4$	B <sub>3</sub>	Р				9			
	0.25±0.15	0.15+0.20/-0.05	0.30±0.15	0.5±0.1				1			

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±3 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	260 °C ±5 °C, 5 s ±1 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High Temperature Exposure	±3 %	+125 °C, 100 h
Load Life in Humidity	±3 %	60 °C±2 °C, 90 % to 95 %RH, Rated Power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 °C	±5 %	70 °C±2 ℃, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



# **Chip Attenuator**



Series: EXB 14AT, 24AT

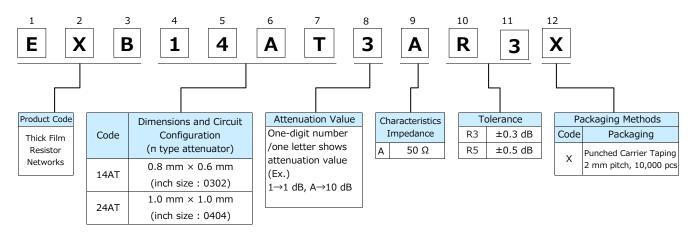
#### **Features**

- Unbalanced π type attenuator circuit in one chip EXB14AT(0.8 mm×0.6 mm) , EXB24AT(1.0 mm×1.0 mm)
- Reduced mounting area :
  - EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors
  - EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors
- Mounting cost reduction : (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

#### **Recommended Applications**

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

#### **Explanation of Part Numbers**



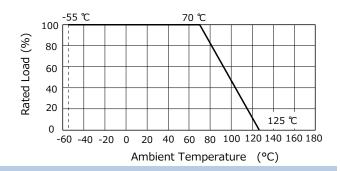
#### Ratings

Part No.	EXB14AT, EXB24AT
Attenuation Value	1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB*
Attenuation Value Tolerance	1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB
Attenuation value Tolerance	6 dB, 10 dB : ±0.5 dB
Characteristic Impedance	50 Ω
Power Rating at 70 °C	0.04 W/ package
Frequency Range	DC to 3.0 GHz
VSWR (Voltage Standing Wave Ratio)	1.3 max.
Number of Resistors	3 resistors
Number of Terminals	4 terminals
Category Temperature Range	−55 °C to +125 °C

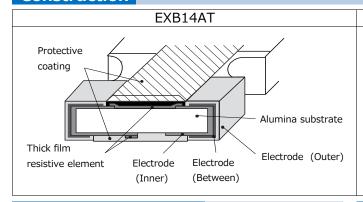
<sup>\*</sup> Please inquire about the other Attenuator value

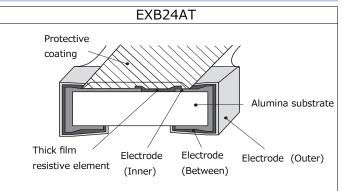
#### **Power Derating Curve**

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

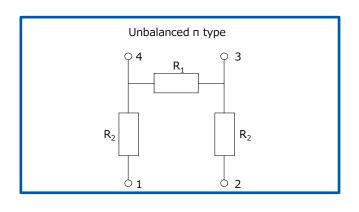


#### Construction

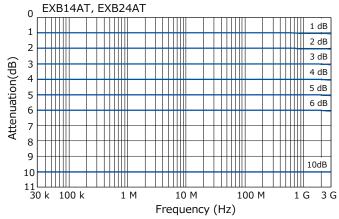




#### **Circuit Confi guration**

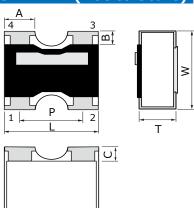


#### **Attenuation-Frequency Characteristics**

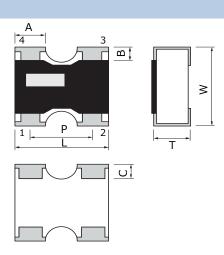


#### Dimensions in mm (not to scale)

EXB14AT



EXB24AT



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 3, 4. < Marking Configuration>
The bar marking for recognizing terminal direction is located on the side of terminal 4.

Part No.	Dimensions (mm)										
Tare No.	L	W	Т	А	В	С	P(typical value)	(g/1000 pcs)			
EXB14AT	$0.80\pm0.10$	0.60±0.10	$0.35 \pm 0.10$	0.35±0.10	$0.15\pm0.10$	$0.15\pm0.10$	0.50	0.7			
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1			



Surface	Mount Resistors Seri	es	Pa	ackaging (Standard	Quantity: pcs/red	el)
		Size mm	Pressed	Punched	Punched	Embossed
Products	Part No.	(inch)	Carrier Taping	Carrier Taping	Carrier Taping	Carrier Taping
			(2 mm pitch )	(2 mm pitch )	(4 mm pitch )	(4 mm pitch )
	ERJXGN	0402(01005)	20,000 *	_	_	40,000 **
	ERJ1GN	0603(0201)	15,000	_	_	_
	ERJ2GE	1005(0402)	_	10,000	_	
	ERJ3GE	1608(0603)	_	_	5,000	
Thick Film	ERJ6GE	2012(0805)	_	_	5,000	_
Chip Resistors	ERJ8GE	3216(1206)	_	_	5,000	_
	ERJ14	3225(1210)	_	_		5,000
	ERJ12	4532(1812)	_	_	_	5,000
	ERJ12Z	5025(2010)	_	_	_	5,000
	ERJ1T	6432(2512)	_	_	_	4,000
	ERJXGN	0402(01005)	20,000 *	_	_	40,000 **
	ERJ1GN/1RH	0603(0201)	15,000	_	_	_
	ERJ2RC/2RH/2RK	1005(0402)	_	10,000	_	_
	ERJ3RB/3RE/3EK	1608(0603)	_	_	5,000	_
Precision	ERJ6RB/6RE/6EN	2012(0805)	_	_	5,000	
Thick Film	ERJ8EN	3216(1206)	_	_	5,000	
Chip Resistors	ERJ14N	3225(1210)	_	_		5,000
	ERJ12N	4532(1812)	_	_	_	5,000
	ERJ12S	5025(2010)	_	_	_	5,000
	ERJ1TN	6432(2512)	_	_	_	4,000
Metal Film	ERA1A	0603(0201)	15,000	_	_	_
(Thin Film)	ERA2A/2V	1005(0402)	_	10,000	_	_
Chip Resistors,	ERA3A/3V/3K	1608(0603)	_	_	5,000	_
High Reliability	ERA6A/6V/6K	2012(0805)	_	_	5,000	_
Туре	ERA8A	3216(1206)		_	5,000	
	ERJ2LW/2BW	1005(0402)	10,000	_	_	
	ERJ2BS/2BQ	1005(0402)	_	10,000	_	
	ERJ3L/3B/3R/L03	1608(0603)		-	5,000	
	ERJ6L/6B/6C	1000(0000)				
Thick Film	ERJ6D/6R/L06	2012(0805)	_	_	5,000	_
Chip Resistors/Low	ERJ8B/8C/8R/L08	3216(1206)	_	_	5,000	_
Resistance Type	ERJ14B/14R/L14	3225(1210)	_	_		5,000
	ERJ12R/L12	4532(1812)	_	_	_	5,000
	ERJ12Z/L1D	5025(2010)	_	_	_	5,000
	ERJ1TR	6432(2512)	_	_	_	4,000
	ERJL1W	6432(2512)	_	_	_	3,000
Current Sensing Resistors, Metal	ERJMS4	6432(2512)	_	_	_	2,000
Plate Type	ERJMB1	2550(1020)	_	_	_	3,000
	ERJA1	3264(1225)	_	_	_	4,000
High Power Chip Resistors/Wide	ERJB1/ERJC1 <sup>(1)</sup> ERJD1 <sup>(2)</sup>	2550(1020)	_	_	_	5,000
Terminal Type	ERJB2/ERJD2 <sup>(2)</sup>	1632(0612)	_		5,000	
	ERJB3	1220(0508)	_		5,000	_

<sup>\*</sup>W8P2 : Width 8 mm, Pitch 2 mm, \*\* W4P1 : Width 4 mm, Pitch 1 mm

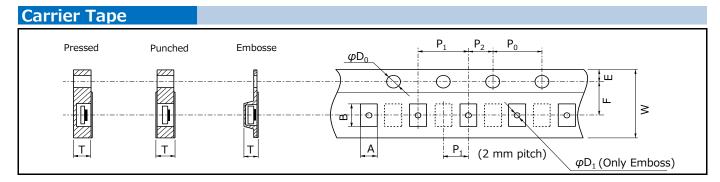
<sup>(1)</sup> Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

<sup>(2)</sup> Low TCR High Power Chip Resistors / Wide Terminal Type



Products	Surface	Mount Resistors Sei	ries	Pā	ackaging (Standard	Quantity: pcs/re	el)
Products			Sizo mm				
High Precision Thick   RIJPB3	Products	Part No.		Carrier Taping	Carrier Taping	Carrier Taping	Carrier Taping
Film Chip Resistors   ERIPBG   2012(0805)   -   -     5,000   -     -     5,000   -         5,000   -			` '	(2 mm pitch )	(2 mm pitch )	(4 mm pitch )	(4 mm pitch )
Anti-Surge Thick Film Chip Resistors  ERJP03/PA3	_	ERJPB3		_	_	5,000	_
Anti-Surge Thick   Film Chip Resistors   ERIPO3/PA3   1608(0603)	Film Chip Resistors	ERJPB6	2012(0805)	_	_	5,000	
Rand-Surger Into:   ERJPO6   2012(0805)		ERJPA2	1005(0402)	_	10,000	ı	1
Film Chip Resistors   Period	Anti Surgo Thick	ERJP03/PA3	1608(0603)	_	_	5,000	_
ERJPOB   3216(1206)		ERJP06	2012(0805)	_	_	5,000	_
Anti-Pulse Thick Film Chip Resistors	Tilli Cilip Resistors	ERJP08	3216(1206)	_	_	5,000	_
## ERTOR ## S216(1206) — — — 5,000 — — FITICH Chip Resistors   Film Chip Resistors		ERJP14	3225(1210)	_	_	_	5,000
Film Chip Resistors    RATUS   STATE	Anti Dulco Thick	ERJT06	2012(0805)	_	_	5,000	_
ERT14   3225(1210)		ERJT08	3216(1206)	_	_	5,000	_
ERJUD1	Fill Chip Resistors	ERJT14	3225(1210)	_	_	_	5,000
ERJS02/U02		ERJU0X	0402(01005)	20,000	_	_	_
RRJS02/U02		ERJU01	0603(0201)	15,000	_	_	_
Anti-Sulfurated Thick Film Chip Resistors  ERJ06/U6Q ERJ07/U12 ERJ07/U12 ERJ07/U12 ERJ07/U12 ERJ07/U12 ERJ07/U12 ERJ07/U13 ERJ07/U14 ERJ07/U15 ERJ07/U17		ERJS02/U02	1005(0402)	<u> </u>	10,000		_
Anti-Sulfurated Thick Film Chip Resistors  ERJS08/U08  ERJS14/U14  ERJS12/U12  ERJS12/U12  ERJS12/U10  ERJS12/U11  ERJS12/U11  ERJS12/U11  ERJS17/U1T  ERJS17/U1T  ERJS18  Anti-Sulfurated Thick Film Chip Resistors / Precision Type  Anti-Sulfurated Thick Film Chip Resistors / Precision Type  ERJS18  ERJS08/U08  ERJS18  ERJS08/U08  ERJS18  Anti-Sulfurated Thick Film Chip Resistors / Precision Type  ERJUGR  ERJS18  ERJS08  ERJUGR  ERJUGR  ERJUGR  2012(0805)  ERJUGR  ERJUGR  2012(0805)  ERJUGR  ERJUGR  2012(0805)  ERJUGR  ERJUGR  2012(0805)  ERJUGR  ERJ		•	1608(0603)	_	_	5,000	1
Thick Film Chip Resistors    ERJUSA/USES   Chip Resistors	Anti-Sulfurated	•					_
Chip Resistors  ERJS08/U08  ERJS14/U14  3225(1210)  ERJS12/U12  4532(1812)  ERJS1D/U1D  5025(2010)  ERJS1D/U1D  5025(2010)  ERJS1D/U1T  6432(2512)  ERJU2R  1005(0402)  ERJU2R  1005(0402)  ERJU2R  1005(0402)  ERJU3R  1608(0603)  ERJU3R  1608(0603)  ERJU6R  2012(0805)  ERJU9B  Anti-Sulfurated Thick Film Chip Resistors / Anti-Surger Type  ERJU9B  2012(0805)  ERJU9B  3216(1206)  ERJUPB  3216(1206)  ERJUPB  3216(1206)  ERJUPB  3216(1206)  ERJUPB  3216(1206)  ERJUPB  2012(0805)  ERJUPB  3216(1206)  ERJUPB  3216(1206)  ERJUPB  ERJUPB  2012(0805)  ERJUPB  3216(1206)  ERJUPB  2012(0805)  ERJUPB  3216(1206)  ERJUPB  ERJUPB  3216(1206)  ERJUPB  ERJUPB  2012(0804)  ERJUPB  ERJUPB  ERJUPB  ERJUPB  Anti-Surfurated  ERJUPB  ERJUPB  ERJUPB  ERJUPB  Anti-Surfurated  Chip Resistor Array  ERJUPB  ERJUPB  ERJUPB  ERJUPB  Anti-Surfurated  Chip Resistor Array  ERJUB  ERJUPB  ERJUPB  ERJUPB  Anti-Surfurated  Chip Resistor Array  ERJUPB  ERJUPB  Anti-Surfurated  Chip Resistor Array  ERJUB  ERJUPB			2012(0805)	_	_	5,000	
ERJS14/U14   3225(1210)       5,000			3216(1206)	_	_	5,000	_
RRJS12/U12	·	·	` ′	_	_	- -	5 000
REJSID/U1D   5025(2010)         5,000		-			_	_	·
Anti-Sulfurated Thick Film Chip Resistors / Precision Type Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type  Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type  Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type  ERJUPB 3216(1206)		·			_		
Anti-Sulfurated Thick Film Chip Resistors / Arti-Sulfurated Thick Film Chip Resistors / Anti-Sulfurated Thick Film Chip Resistors / Anti-Sulfurated Thick Film Chip Resistors / Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type		•			_		
Thick Film Chip   Resistors / Precision   Type   ERJU3R   1608(0603)   -	Anti-Sulfurated	·			10.000		<del>-</del> ,000
Resistors / Precisions   Fred   FRUU6R   2012(0805)				<u> </u>	10,000		
Anti-Sulfurated Thick Film Chip Resistors / Anti-Surger Type	Resistors / Precision			_	_		_
Thick Film Chip Resistors / Anti-Surge Type  ERJUP8  3216(1206)  ERJUP8  3216(1206)  Thick Film Chip Resistors / Anti-Surge Type  ERJUP8  3216(1206)  ERJUP8  3216(1206)  Thick Film Chip Resistor Array  ERJUP8  3216(1206)  ERJUP8  3216(1206)  Thick Film Chip Resistor Array  Thick Film Chip Thic	Туре				_		
Resistors / Anti-Surge	Anti-Sulfurated	ERJUP3	1608(0603)		_	5,000	_
Type         ERJUP8         3216(1206)         —         —         5,000         —           EXB14V         0806(0302)         —         10,000         —         —           EXB24V         1010(0404)         —         10,000         —         —           EXB34V         1616(0606)         —         —         5,000         —           EXB18V         1616(0606)         —         —         5,000         —           EXB18V         1406(0502)         —         10,000         —         —           EXB18V         2010(0804)         —         10,000         —         —         —           EXB38V         2010(0804)         —         10,000         —         —         —         —           EXB38V         3216(1206)         —         —         5,000         —         —         —         2,500         —         —         2,500         —         —         2,500         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —	•	ERJUP6	2012(0805)	_	_	5,000	_
EXB14V		EDILIDO	2245(4225)			F 000	
Chip Resistor Array         EXB24V         1010(0404)         —         10,000         —	туре	ERJUP8	3216(1206)		_	5,000	_
Chip Resistor Array         EXB34V         1616(0606)         -         -         5,000         -           EXB18V         1406(0502)         -         10,000         -         -           EXB18V         2010(0804)         -         10,000         -         -         -           EXB18V         3216(1206)         -         -         5,000         -         -         -         2,500         -         -         2,500         -         -         -         2,500         -         -         -         2,500         -         -         -         2,500         -         -         -         -         2,500         -         -         -         -         2,500         -         -         -         -         -         -         -         -         -         -         -         - </td <td></td> <td>EXB14V</td> <td></td> <td>_</td> <td>10,000</td> <td>_</td> <td>_</td>		EXB14V		_	10,000	_	_
Chip Resistor Array         EXBV4V         1616(0606)         —         —         5,000         —           Array         EXB18V         1406(0502)         —         10,000         —         —           EXB28V         2010(0804)         —         10,000         —         —         —           EXB38V         3216(1206)         —         —         5,000         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         2,500         —         —         —         —         2,500         —         —         —         —         —         —         —         —         —         —         —         —         —         —         —         —		EXB24V	1010(0404)	_	10,000	_	_
Chip Resistor Array         EXB18V         1406(0502)         —         10,000         —         —           EXB28V         2010(0804)         —         10,000         —         —           EXBN8V         2010(0804)         —         10,000         —         —           EXB38V         3216(1206)         —         —         5,000         —           EXBV8V         3216(1206)         —         —         5,000         —           EXBSBV         5022(2009)         —         —         —         2,500           EXBLHV         3816(1506)         —         —         —         2,500           EXBU14         0806(0302)         —         10,000         —         —           EXBU18         1406(0502)         —         10,000         —         —           EXBU24         1010(0404)         —         10,000         —         —           EXBU24         1010(0404)         —         10,000         —         —           EXBU28         2010(0804)         —         —         5,000         —           EXBU28         3216(1206)         —         —         5,000         —           Chip Resistor <td></td> <td>EXB34V</td> <td>1616(0606)</td> <td>_</td> <td>_</td> <td></td> <td>_</td>		EXB34V	1616(0606)	_	_		_
Chip Resistor Array         EXB28V         2010(0804)         —         10,000         —         —           EXBN8V         2010(0804)         —         10,000         —         —           EXB38V         3216(1206)         —         —         5,000         —           EXBV8V         3216(1206)         —         —         5,000         —           EXBS8V         5022(2009)         —         —         —         2,500           EXB2HV         3816(1506)         —         —         —         2,500           EXB2HV         3816(1506)         —         —         —         —         2,500           EXBU14         0806(0302)         —         10,000         —		EXBV4V	1616(0606)	_	_	5,000	1
Array  EXB28V	Chin Posistor	EXB18V	1406(0502)	_	10,000		
EXBNSV 2010(0804) — 10,000 — — 5,000 — EXBVSV 3216(1206) — — 5,000 — 2,500 — 2	· ·	EXB28V	2010(0804)	_	10,000		1
EXBV8V 3216(1206) — — — — 5,000 — — 2,500 EXB2HV 3816(1506) — — — — 5,000 — — — — — — — — — — — — — — — — — —	Array	EXBN8V	2010(0804)	_	10,000	_	_
EXBS8V 5022(2009) — — — — 2,500  EXB2HV 3816(1506) — — 5,000 —  EXBU14 0806(0302) — 10,000 — — —  EXBU18 1406(0502) — 10,000 — — —  EXBU24 1010(0404) — 10,000 — — —  EXBU34 1616(0606) — — 5,000 — —  EXBU28 2010(0804) — 10,000 — — —  EXBU38 3216(1206) — — 5,000 — —  EXBU2H 3816(1506) — — 5,000 — —  Chip Resistor Parsy  EXBD 3216(1206) — — 5,000 — —  Chip Resistor EXBE 4021(1608) — — — 4,000  EXBQ 3816(1506) — — — 4,000  EXBQ 3816(1506) — — 5,000 — —  Chip Attenuator		EXB38V	3216(1206)	_	_	5,000	
EXB2HV         3816(1506)         —         —         5,000         —           EXBU14         0806(0302)         —         10,000         —         —           EXBU18         1406(0502)         —         10,000         —         —           EXBU24         1010(0404)         —         10,000         —         —           EXBU34         1616(0606)         —         —         5,000         —           EXBU28         2010(0804)         —         10,000         —         —           EXBU28         2010(0804)         —         10,000         —         —           EXBU28         3216(1206)         —         —         5,000         —           EXBU29         3816(1506)         —         —         5,000         —           Chip Resistor         EXBE         4021(1608)         —         —         5,000         —           Networks         EXBA         6431(2512)         —         —         4,000           EXBQ         3816(1506)         —         —         5,000         —           Chip Attenuator         EXB14AT         0806(0302)         —         10,000         —         —		EXBV8V	3216(1206)	_	_	5,000	-
Anti-Sulfurated Chip Resistor Array  EXBU14  EXBU34  Chip Resistor Array  EXBU38  EXBU34  I010(0404)  EXBU34  I010(0404)  EXBU34  I010(0806)  EXBU38  I010(0804)  EXBU38  I010(0804)  I010(0800)  I010		EXBS8V	5022(2009)	_	_	_	2,500
Anti-Sulfurated Chip Resistor Array  EXBU24  Chip Resistor Array  EXBU24  EXBU24  1010(0404)  EXBU34  1616(0606)  EXBU28  2010(0804)  EXBU28  2010(0804)  EXBU38  3216(1206)  EXBU2H  3816(1506)  Chip Resistor  Networks  EXBD  3216(1206)  EXBD  Another Afternator		EXB2HV	3816(1506)	_	_	5,000	_
Anti-Sulfurated Chip Resistor Array  EXBU24		EXBU14	0806(0302)	_	10,000	_	_
Anti-Sulfurated Chip Resistor Array  EXBU24    1010(0404)		EXBU18	1406(0502)		10,000		
EXBU34   1616(0606)   -	Anti Culturatad	EXBU24	1010(0404)				
EXBU28   2010(0804)   -   10,000   -   -			1616(0606)			5,000	
EXBU38       3216(1206)       —       —       5,000       —         EXBU2H       3816(1506)       —       —       5,000       —         EXBD       3216(1206)       —       —       5,000       —         Chip Resistor       EXBE       4021(1608)       —       —       —       4,000         Networks       EXBA       6431(2512)       —       —       —       4,000         EXBQ       3816(1506)       —       —       5,000       —         Chip Attenuator       EXB14AT       0806(0302)       —       10,000       —       —	Chip Resistor Array		2010(0804)	_	10,000	_	_
EXBU2H       3816(1506)       —       —       5,000       —         EXBD       3216(1206)       —       —       5,000       —         Chip Resistor       EXBE       4021(1608)       —       —       —       4,000         Networks       EXBA       6431(2512)       —       —       —       4,000         EXBQ       3816(1506)       —       —       5,000       —         Chip Attenuator       EXB14AT       0806(0302)       —       10,000       —       —			3216(1206)	_	_	5,000	_
Chip Resistor         EXBD         3216(1206)         —         —         5,000         —           Networks         EXBE         4021(1608)         —         —         —         4,000           EXBA         6431(2512)         —         —         —         4,000           EXBQ         3816(1506)         —         —         5,000         —           Chip Attenuator         EXB14AT         0806(0302)         —         10,000         —         —				_	_		_
Chip Resistor         EXBE         4021(1608)         —         —         —         4,000           Networks         EXBA         6431(2512)         —         —         —         4,000           EXBQ         3816(1506)         —         —         5,000         —           Chip Attenuator         EXB14AT         0806(0302)         —         10,000         —         —				_	_		_
Networks         EXBA         6431(2512)         —         —         —         4,000           EXBQ         3816(1506)         —         —         5,000         —           Chip Attenuator         EXB14AT         0806(0302)         —         10,000         —         —	Chip Resistor			_	_		4,000
EXBQ 3816(1506) — — 5,000 —  Chip Attenuator EXB14AT 0806(0302) — 10,000 — —				_	_	_	•
Chip Attenuator				_	_	5,000	_
( NID ATTENUATOR	Chin All	-		_	10,000	_	_
	Cnip Attenuator	EXB24AT	1010(0404)	_	10,000	_	_





Pressec	l Carrier	Taping	j (2 mi	m Pitcl	1)						
	stors / Precisi	on Chip / N	1etal Film(	Thin Film)	Chip / Low	Resistance	/ Anti-Su	lfurated		( Unit	: mm)
Part No.	Size mm (inch)	Α	В	W	F	Е	P <sub>1</sub>	P <sub>2</sub>	$P_0$	$\varphi D_0$	Т
ERJXGN	0402	0.24±0.03	0.45+0.03								0.31±0.05
ERJU0X	0402	0.24±0.03	0.43±0.03								
ERJ1GN											
ERJ1R□	0603	0.30+0.05	0.60+0.05							1.50	0.42±0.05
ERJU01	0003	0.38±0.05	0.06±0.05	8.00±0.20	3.50±0.05	1./5±0.10	2.00±0.10	2.00±0.05	4.00±0.10	+0.10/0	0.42±0.05
ERA1A										,	
ERJ2LW	1005	$0.68 \pm 0.10$	1.20±0.10	1							0.60±0.05
ERJ2BW	1005	0.67±0.10	1.17±0.10	1							0.61±0.05

Punche	Punched Carrier Taping (2 mm Pitch)											
<ul> <li>Chip Resist</li> </ul>	• Chip Resistors / Precision Chip / Metal Film(Thin Film)Chip / Low Resistance / Anti-Surge / Anti-Sulfur / Metal Foil Type (Unit:mm)											
Part No.	Size mm (inch)	Α	В	W	F	Е	P <sub>1</sub>	$P_2$	P <sub>0</sub>	$\varphi  D_0$	Т	
ERJ2□												
ERJPA2										1.50		
ERJ□□2	1005	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	+0.10/0	0.52±0.05	
ERJ□2□										+0.10/0		
ERA2□												

<ul><li>Chip Resis</li></ul>	Chip Resistor Array / Anti-Sulfurated Chip Resistor Array / Chip Attenuator (Unit: mm)										
Part No.	Size mm (inch)	Α	В	W	F	Е	P <sub>1</sub>	$P_2$	$P_0$	$\varphi D_0$	Ť
EXB14V	0806	0.70	0.95								
EXB14AT	0800	+0.10/-0.05	+0.05/-0.10								
EXB18V	1406		1.60±0.10								
EXB24V										1 50	
EXBU24	1010		1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05
EXB24AT		1.20±0.10								+0.10/0	
EXB28V											
EXBU28	2010		2.20±0.10								
EXBN8V											

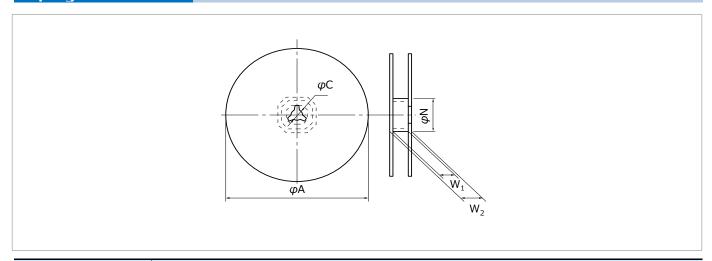
# Punched Carrier Taping (4 mm Pitch)

	stors / Precisi		1etal Film(	Thin Film)(	Chip / Low	Resistance	e / High Po	wer / High	Precision	/ Anti-Surg	ge /
Anti-Pulse	/ Anti-Sulfur	ated								( Unit	:: mm)
Part No.	Size mm (inch)	Α	В	W	F	E	P <sub>1</sub>	$P_2$	$P_0$	$\varphi  D_0$	T
ERJ3□											
ERJ3LW(10mΩ)											
ERJ3BW											0.70±0.05
ERJ□□3	1608	1.10±0.10	1.90±0.10								0.70±0.03
ERJ□3□											
ERA3□											
ERJ3LW(5m $\Omega$ )											
ERJ6□											
ERJ□□6	2012										
ERJ□6□	2012	1.65±0.15	2.50±0.20							1.50	0.84±0.05
ERA6□				8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	+0.10/0	
ERJB3	1220									10.10,0	
ERJ6BW											
ERJ6LW	2012	1.55±0.15	2.30±0.20								0.94±0.05
ERJ6C											0.94±0.03
ERJ8□											
ERJ8□W	3216										
ERJ□□8	3210	2.00±0.15	3.60±0.20								0.84±0.05
ERA8											
ERJB2 ERJD2	1632										

Part No.	Size mm (inch)	Α	В	W	F	F		1	$P_2$	$P_0$	$\varphi D_0$	Т
EXB34V				VV	!	L		1	' 2	• 0	$\varphi D_0$	
XBU34	1616		1.95±0.20									
XB38V	3216		3.60±0.20									0.70±0.0
XBU38	3210	4 05 10 45	3.00±0.20									0.70±0.0
XB2HV	3816	1.95±0.15	4.10±0.15								1.50	
XBU2H				8.00±0.20	3.50±0.05	1.75±0.3	4.00=	±0.10	2.00±0.05	4.00±0.10	+0.10/0	
XBV4V	1616		1.95±0.20									0.84±0.0
XBV8V	3216		3.60±0.20									
XBD	3216	2.00±0.20	3.60±0.20									0.84±0.1
XBQ	3816	1.90±0.20	4.10±0.20									0.64±0.0
Emboss	sed Carri	er Tapi	ing (1	mm Pi	tch)							
● Chip Resi	stors										( Uni	t : mm)
Part No.	Size mm (inch)	Α	В	W	F	Е	F	1	$P_2$	$P_0$	$\varphi D_0$	T
RJXGN	0402	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.	10 1.00	±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max
Emboso	od Carri	or Tani	na (A	mm Di	tch)							
	sed Carri								/ A .: 6	16 . 1		
	stors / Precisi		,				•		· .	_		t : mm)
Part No.	Size mm (inch)	Α	В	W	F	Е	$P_1$	P <sub>2</sub>	P <sub>0</sub>	$\varphi D_0$	Т	$\varphi D_1$
RJ14□	3225	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00
RJ□14 RJ12□	+											+0.10/0
RJ□12	4532	3.50±0.20	4.80±0.20									
RJ12Z	5025											
RJ12S												
RJ□1D		2 00+0 20	5.30±0.20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
RJB1		2.60±0.20	5.30±0.20	12.00	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		15
RJC1	2550			±0.30	5.50±0.20				-5.15	10110/0		15 min
RJD1												
RJ1T□												
RJ□1T	6432	3.60±0.20	6.90±0.20									
RJL1W											1.60±0.10	
	3264	3.50±0.20	$16.80 \pm 0.20$								1.10±0.20	
RJAI			0.00=0.20		II							
	Sensing Resist										( Uni	t : mm)
				W	F	E	P <sub>1</sub>	P <sub>2</sub>	P <sub>0</sub>	$\varphiD_0$	( Uni	t : mm) φ D <sub>1</sub>
• Current S Part No.	Size mm (inch)	ors, Metal	Plate Type B	12.00	-					, ,	T	
• Current S Part No.	Sensing Resisto	ors, Metal	Plate Type	12.00 ±0.30	F 5.50±0.10	1.75	4.00	2.00	4.00	1.50	,	
Part No.	Size mm (inch)	ors, Metal	Plate Type B	12.00 ±0.30	-	1.75 ±0.10				, ,	T	φD <sub>1</sub>
Part No.  RJMB1  RJMS4	Size mm (inch)	ors, Metal A 2.90±0.20 3.50±0.20	Plate Type B 5.40±0.20 6.90±0.20	12.00 ±0.30 12.00 ±0.30	5.50±0.10	1.75 ±0.10	4.00	2.00	4.00	1.50	T 1.55±0.20 1.60±0.20	φD <sub>1</sub>
Part No.  RJMB1  RJMS4	Size mm (inch) 2550 6432	ors, Metal A 2.90±0.20 3.50±0.20	Plate Type B 5.40±0.20 6.90±0.20	12.00 ±0.30 12.00 ±0.30	5.50±0.10	1.75 ±0.10	4.00	2.00	4.00	1.50	T 1.55±0.20 1.60±0.20	φ D <sub>1</sub> — 1.5 mir
Current S Part No.  RJMB1  RJMS4  Chip Resi Part No.	Size mm (inch)  2550  6432  stor Array / C	ors, Metal A 2.90±0.20 3.50±0.20	Plate Type B 5.40±0.20 6.90±0.20 or Network B	12.00 ±0.30 12.00 ±0.30	5.50±0.10 5.50±0.10	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	T 1.55±0.20 1.60±0.20 ( Uni	φ D <sub>1</sub> -  1.5 mir  t : mm)
Part No.  ERJMB1  ERJMS4  Chip Resi	Size mm (inch)  2550  6432  stor Array / C Size mm (inch)	ors, Metal A 2.90±0.20 3.50±0.20 hip Resisto	Plate Type  B  5.40±0.20  6.90±0.20  or Network  B  5.70±0.20	12.00 ±0.30 12.00 ±0.30	5.50±0.10 5.50±0.10	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	T 1.55±0.20 1.60±0.20 ( Uni	φ D <sub>1</sub> -  1.5 mir  t : mm)



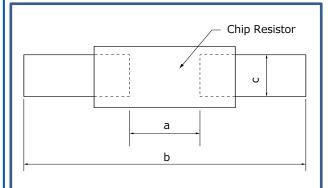
# **Taping Reel**



Tape width(W)	Dimensions (mm)								
rape width(w)	φΑ	φN	φC	$W_1$	$W_2$				
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5				
8 mm width	180.0 0/-1.5	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0				
12 mm width	160.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0				
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0				

#### **Recommended Land Pattern**

• An example of a land pattern for the Rectangular Type is shown below.



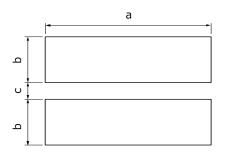
High power (double-sided resistive elements str	ructure) type

Part No.	Size mm	Dim	ensions(r	nm)
raic No.	inch	а	b	С
ERJ2LW/2BW	1005 0402	0.52	1.4 to 1.6	0.4 to 0.6
ERJ3LW/3BW	1608 0603	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (10 to 13 mΩ)	2012 0805	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4
ERJ8BW				
ERJ8CW (10 to 16 mΩ)	3216 1206	1.2	4.4 to 5.0	1.3 to 1.8
ERJ8CW (18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8

Size	Dimensions(mm)			
mm/inch	a	b	С	
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25	
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35	
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6	
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0	
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4	
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8	
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8	
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5	
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8	
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5	
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5	

<sup>\*</sup> ERJL1W

An example of a land pattern for High Power Chip Resistors / Wide Terminal Type is shown below.

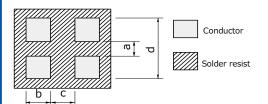


Part No.	Dimensions(mm)			
rait No.	a	b	С	
ERJA1	6.4	1.70	0.60	
ERJB1				
ERJC1 <sup>(1)</sup>	5.0	1.30	0.75	
ERJD1 <sup>(2)</sup>				
ERJB2	3.2	0.95	0.70	
ERJD2 <sup>(2)</sup>	3.2	0.95	0.70	
ERJB3	2.0	0.80	0.60	

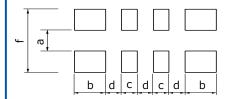
- $\hbox{(1) Anti-Sulfurated High Power Chip Resistors/Wide Terminal Type}\\$
- (2) Low TCR High Power Chip Resistors/Wide Terminal Type

#### **Recommended Land Pattern**

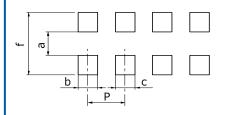
• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



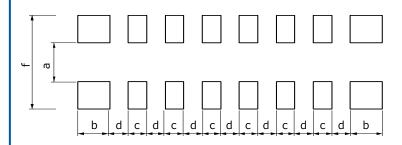
Part No.	Dimensions(mm)				
Part No.	a	b	С	d	
EXB14V	0.30	0.30	0.30	0.80 to 0.90	
EXB14A	0.30	0.30	0.30	0.80 to 0.90	
EXB24V					
EXBU24	0.5	0.35 to 0.40	0.30	1.4 to 1.5	
EXB24A					



Part No.	Dimensions(mm)				
rait No.	a	b	С	d	f
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00



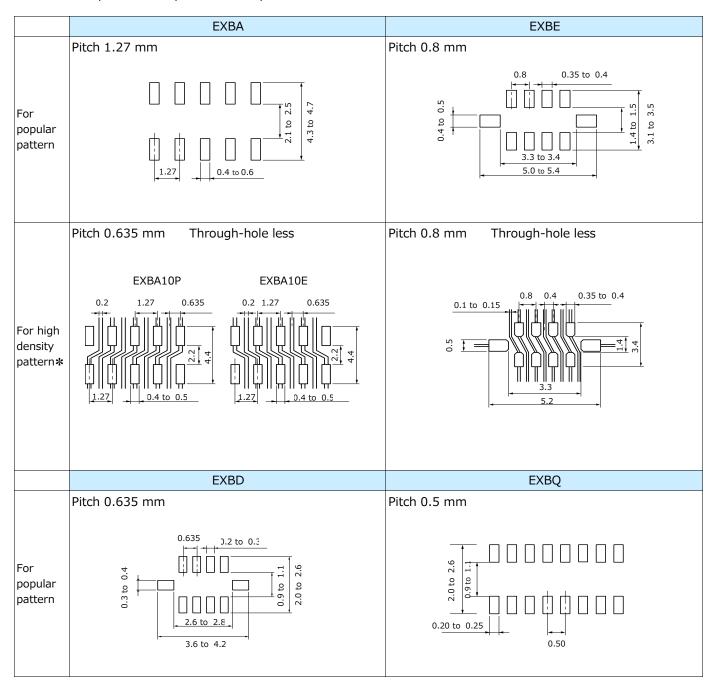
Part No.	Dimensions(mm)					
Part No.	a	b	С	f	Р	
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40	
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80	
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80	
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27	



Part No.	Dimensions(mm)					
rait No.	a	b	С	d	f	
EXB2HV	1.00	0.425	0.25	0.25	2.00	
EXBU2H	1.00	0.423	0.25	0.25	2.00	

#### **Recommended Land Pattern**

• An example of a land pattern for Chip Resistor Networks is shown below.



\* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.



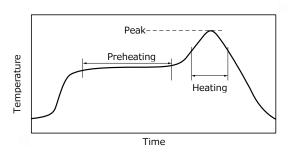
#### **Recommended Soldering Conditions**

Recommendations and precautions are described below.

#### Rectagular Type

#### • Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



#### For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

#### For lead-free soldering (Example : Sn/Ag/Cu)

To lead thee soldering (Example: ShirAgrea)				
	Temperature	Time		
Preheating	150 ℃ to180 ℃	60 s to 120 s		
Main heating	Above 230 ℃	30 s to 40 s		
Peak	max. 260 ℃	max. 10 s		

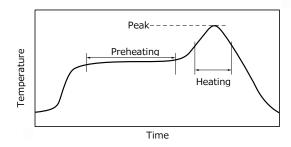
#### Recommended soldering conditions for flow

	For soldering		For lead-free soldering	
	Temperature Time		Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

#### Chip Resistor Array, Chip Resistor Networks and Chip Attenuator

#### • Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



#### For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

#### For lead-free soldering (Example: Sn/Ag/Cu)

3 ( 1   1   1   3   1							
	Temperature	Time					
Preheating	150 ℃ to180 ℃	60 s to 120 s					
Main heating	Above 230 ℃	30 s to 40 s					
Peak	max. 260 ℃	max. 10 s					

#### Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.

#### Standard for Resistance Value and Resistance Tolerance

#### **Basis Standard**

IEC Publication 60062: Marking codes for resistors and capacitors.

IEC Publication 60063: Preferred number series for resistors and capacitors.

JIS C 5062: Marking codes for resistors and capacitors.

JIS C 5063: Preferred number series for resistors and capacitors.

#### **Resistance Values**

The resistance values are notched by "Ratio" below in each series.

Series	Resistance Tolerance (Standard)	Ratio	Remarks
E6	±20 %	<sup>6</sup> √10=1.46	
E12	±10 %	¹²√10=1.21	
E24	± 5 %	24√10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	48√10=1.05	Shows on and educage
E96	± 1 %	96√10=1.02	

#### How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10  $\Omega$ .

The examples of a three digit number

The examples of a time digit number							
Resistance Code	Value in ohms $(\Omega)$						
R56	0.56						
5R6	5.6						
100	10						
271	270						
102	1 k						
273	27 k						
104	100 k						
275	2.7 M						
106	10 M						
107	100 M						

The examples of a four digit number

Resistance Code	Value in ohms (Ω)
R562	0.562
5R62	5.62
56R2	56.2
1000	100
2711	2.71 k
1002	10 k
2713	271 k
1004	1 M
2751	2.71 M
1006	100 M

#### How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance Code	Tolerance (%)	Examples
W	±0.05	W1001 : 1000 Ω±0.05 %
В	±0.1	B1001 : 1000 Ω±0.1 %
С	±0.25	C1001 : 1000 Ω±0.25 %
D	±0.5	D1001 : 1000 Ω±0.5 %
F	±1	F1001 : 1000 Ω±1 %
G	±2	G1001 : 1000 Ω±2 %
J	±5	J101 : 100 Ω±5 %
K	±10	K101 : 100 Ω±10 %
М	±20	M101 : 100 Ω±20 %

# **Standard Resistance Values**

	_	_	_			_	_					_		_			
E6	E12	E24	E48	E96	E6	E12	E24	E48	E96	E6	E12	E24	E48	E96			
10	10	10	100	100	22	22	22	215	215	47	47	47	464	464			
				102					221					475			
			105	105				226	226 226				487	487			
				107					232					499			
		11	110	110			24	237	237			51	511	511			
				113					243					523			
			115	115				249	249				536	536			
	12	12		118		27			255					549			
	12	12	121	121				261	261		56	56	562	562			
				124				-	267					576			
			127	127				274	274				590	590			
		13		130					280					604			
			133	133				287	287			62	619	619			
				137					294					634			
			140	140			30	301	301				649	649			
				143					309					665			
			147	147				316	316	68	68	68	681	681			
15	15	15		150	33	33	33	-	324					698			
			154	154	33	33	33	332	332				715	715			
		1.0		158					340					732			
		16	162	162				348	348			75	750	750			
				165			36	-	357					768			
		18	169	169				365	365				787	787			
				174					374		82			806			
			178	178				383	383			82	825	825			
	18			182		39	39		392					845			
			187	187				402	402				866	866			
				191					412					887			
			196	196			43	422	422			91	909	909			
		20		200					432					931			
			205	205								442	442				953
				210					453					976			

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  Before use of any of these components for equipment that requires a high degree of safety, such as medical instruments, aerospace equipment, disaster-prevention equipment, security equipment, vehicles (automobile, train, vessel), please be sure to contact our sales representative corporation.
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